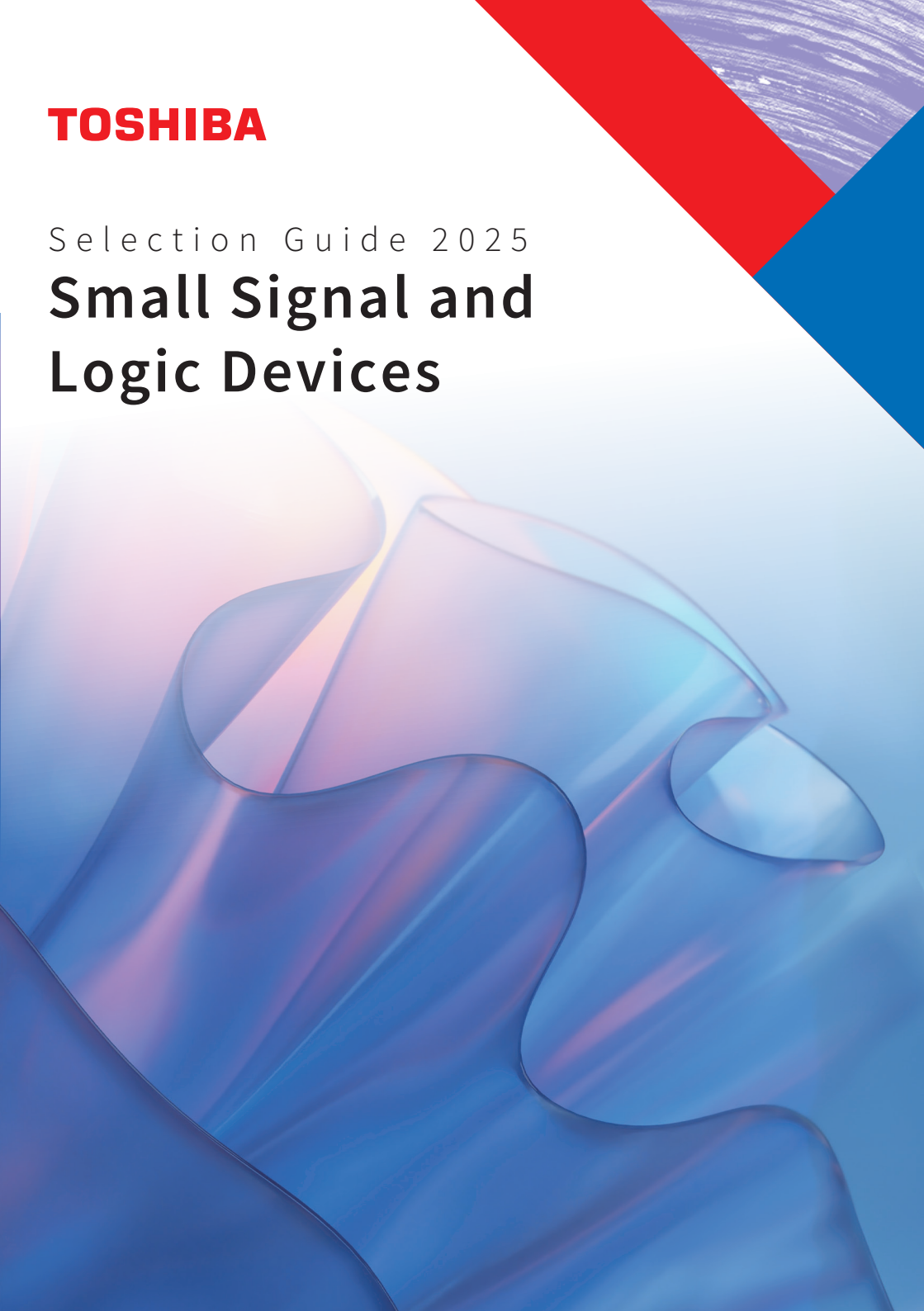




TOSHIBA

Selection Guide 2025

Small Signal and Logic Devices



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1. MOSFETs

Over 500mA Series MOSFETs (Semi-Power Type)

Package Dimensions (unit: mm)

CST3C	CST3 (SOT-883)	VESM (SOT-723)	UFM (SOT-323F)	ES6 (SOT-563)	UF6 (SOT-363F)	WCSP6C
Bottom View  0.8 x 0.6	Bottom View  1.0 x 0.6	 1.2 x 1.2	 2.0 x 2.1	 1.6 x 1.6	 2.0 x 2.1	Bottom View  1.5 x 1.0

P-Channel Single MOSFET

Package	Part Number	V _{DSS} (V)	V _{GSS} (V)	I _D (A)	R _{DS(ON)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note	
					V _{GS} = -1.2 V	V _{GS} = -1.5 V	V _{GS} = -1.8 V	V _{GS} = -2.5 V	V _{GS} = -4 V	V _{GS} = -4.5 V	V _{GS} = -10 V				
CST3C	SSM3J64CTC	\$	-12	+/-10	-1	11300	1310	890	560	-	370	-	-	50	
	SSM3J65CTC	\$	-20	+/-10	-0.7	11300	1550	1070	700	-	500	-	-	48	
CST3	SSM3J56ACT	\$	-20	+/-8	-1.4	4000	900	660	480	-	390	-	1.6	100	
	SSM3J76CT ☆	\$	-20	+/-8	-1.4	4000	900	660	480	-	390	-	1.6	100	Low leakage current
	SSM3J65CT ☆	\$	-20	+/-10	-0.7	11300	1550	1070	700	-	500	-	-	48	
VESM	SSM3J66MFV #	\$	-20	+6/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
	SSM3J56MFV	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
	SSM3J76MFV ☆	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	Low leakage current
WCSP6C	SSM6J771G	\$	-20	+/-12	-5	-	-	-	47.5	-	35	34.7 (@-8 V) 31 (@-8.5 V)	9.8	870	
ES6	SSM6J216FE	\$	-12	+/-8	-4.8	-	88.1	56	39.3	-	32	-	12.7	1040	
	SSM6J213FE	\$	-20	+/-8	-2.6	-	250	178	133	-	103	-	4.7	290	
	SSM6J215FE	\$	-20	+/-8	-3.4	-	154	104	79	-	59	-	10.4	630	
	SSM6J212FE	\$	-20	+/-8	-4	-	94	65.4	49	-	40.7	-	14.1	970	
	SSM6J207FE	\$	-30	+/-20	-1.4	-	-	-	491	-	251	-	-	137	
	SSM6J214FE	\$	-30	+/-12	-3.6	-	-	149.6	77.6	-	57	50	7.9	560	
UFM	SSM3J132TU	\$	-12	+/-6	-5.4	94	39	29	21	-	17	-	33	2700	
	SSM3J135TU	\$	-20	+/-8	-3	-	260	180	132	-	103	-	4.6	270	
	SSM3J145TU #	\$	-20	+6/-8	-3	-	260	180	132	-	103	-	4.6	270	
	SSM3J134TU	\$	-20	+/-8	-3.2	-	240	168	123	-	93	-	4.7	290	
	SSM3J144TU #	\$	-20	+6/-8	-3.2	-	240	168	123	-	93	-	4.7	290	
	SSM3J130TU	\$	-20	+/-8	-4.4	-	63.2	41.1	31	-	25.8	-	24.8	1800	
	SSM3J140TU #	\$	-20	+6/-8	-4.4	-	63.2	41.1	31	-	25.8	-	24.8	1800	
	SSM3J133TU	\$	-20	+/-8	-5.5	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J143TU #	\$	-20	+6/-8	-5.5	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J112TU	\$	-30	+/-20	-1.1	-	-	-	790	-	390	-	-	86	
	SSM3J118TU	\$	-30	+/-20	-1.4	-	-	-	480	-	240	-	-	137	
	SSM3J117TU	\$	-30	+/-20	-2	-	-	-	225	-	117	-	-	280	
UF6	SSM6J422TU #	\$	-20	+6/-8	-4	-	99.6	67.8	51.4	-	42.7	-	12.8	840	
	SSM6J412TU	\$	-20	+/-8	-4	-	99.6	67.8	51.4	-	42.7	-	12.8	840	
	SSM6J424TU	\$	-20	+6/-8	-6	-	54	36	26	-	22.5	-	23.1	1650	
	SSM6J414TU	\$	-20	+/-8	-6	-	54	36	26	-	22.5	-	23.1	1650	
	SSM6J402TU	\$	-30	+/-20	-2	-	-	-	225	-	117	5.3	280		
	SSM6J410TU	\$	-30	+/-20	-2.1	-	-	-	393	-	216	2.9	120		
	SSM6J401TU	\$	-30	+/-20	-2.5	-	-	-	145	-	73	16	730		

☆ New Products

AEC-Q101 qualified, \$ With protection Zener diode between gate and source

UDFN6B (SOT-1220)	SOT-23F	S-Mini (SOT-346)	TSOP6F
Bottom View 			
2.0 x 2.0	2.9 x 2.4	2.9 x 2.5	2.9 x 2.8

P-Channel Single MOSFET

Package	Part Number	V _{DS} (V)	V _{GS} (V)	I _D (A)	R _{DS(ON)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note
					V _{GS} = -1.2 V	V _{GS} = -1.5 V	V _{GS} = -1.8 V	V _{GS} = -2.5 V	V _{GS} = -4 V	V _{GS} = -4.5 V	V _{GS} = -10 V			
UDFN6B	SSM6J512NU	\$ -12	+/-10	-10	-	-	40.1	25.7	20.5 (@-3.6 V)	18.7	16.2 (@-8 V)	19.5	1400	
	SSM6J505NU	\$ -12	+/-6	-12	61	30	21	16	-	12	-	37.6	2700	
	SSM6J511NU	\$ -12	+/-10	-14	-	-	19.2	13.5	11.5 (@-3.6 V)	10	9.1 (@-8 V)	47	3350	
	SSM6J503NU	\$ -20	+/-8	-6	-	89.6	57.9	41.7	-	32.4	-	12.8	840	
	SSM6J502NU	\$ -20	+/-8	-6	-	60.5	38.4	28.3	-	23.1	-	24.8	1800	
	SSM6J501NU	\$ -20	+/-8	-10	-	43	26.5	19	-	15.3	-	29.9	2600	
SOT-23F	SSM6J507NU	\$ -30	+20/-25	-10	-	-	-	-	32	28	20	13.6	1150	
	SSM3J338R	\$ -12	+/-10	-6	-	-	45.3	27.9	21.9 (@-3.6 V)	20.2	17.6 (@-8 V)	19.5	1400	
	SSM3J327R	\$ -20	+/-8	-3.9	-	240	168	123	-	93	-	4.6	290	
	SSM3J377R	# \$ -20	+6/-8	-3.9	-	240	168	123	-	93	-	4.6	290	
	SSM3J331R	\$ -20	+/-8	-4	-	150	100	75	-	55	-	10.4	630	
	SSM3J371R	# \$ -20	+6/-8	-4	-	150	100	75	-	55	-	10.4	630	
	SSM3J328R	\$ -20	+/-8	-6	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J378R	# \$ -20	+6/-8	-6	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J355R	\$ -20	+/-10	-6	-	-	52.3	38.8	-	30.1	-	16.6	1030	
	SSM3J358R	\$ -20	+/-10	-6	-	-	49.3	32.8	27.7 (@-3.6 V)	25.3	22.1 (@-8 V)	38.5	1331	
	SSM3J334R	\$ -30	+/-20	-4	-	-	-	-	136	105	71	5.9	280	
	SSM3J374R	# \$ -30	+10/-20	-4	-	-	-	-	136	105	71	5.9	280	
	SSM3J340R	\$ -30	+20/-25	-4	-	-	-	-	86	73	45	6.2	492	
	SSM3J332R	\$ -30	+/-12	-6	-	-	144	72	-	50	42	8.2	560	
	SSM3J372R	# \$ -30	+6/-12	-6	-	-	144	72	-	50	42	8.2	560	
S-Mini	SSM3J356R	# \$ -60	+10/-20	-2	-	-	-	-	400	360	300	8.3	330	
	SSM3J351R	# \$ -60	+10/-20	-3.5	-	-	-	-	184	164	134	15.1	660	
	SSM3J325F	\$ -20	+/-8	-2	-	311	231	179	-	150	-	4.6	270	
	SSM3J375F	# \$ -20	+6/-8	-2	-	311	231	179	-	150	-	4.6	270	
TSOP6F	SSM3J352F	\$ -20	+/-12	-2	-	-	443	199	-	136	110	5.1	210	
	SSM3J353F	\$ -30	+20/-25	-2	-	-	-	-	274	232	150	3.4	159	
	SSM6J801R	\$ -20	+6/-8	-6	-	88.4	56	39.7	-	32.5	-	12.8	840	
	SSM6J825R	\$ -30	+10/-20	-4	-	-	-	-	86	73	45	6.2	492	
	SSM6J808R	# -40	+10/-20	-7	-	-	-	-	52	48	35	24.2	1020	

AEC-Q101 qualified, \$ With protection Zener diode between gate and source

CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	UFM (SOT-323F)	ES6 (SOT-563)	UF6 (SOT-363F)	WCSP6C
Bottom View 						Bottom View 
1.0 x 0.6	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	1.6 x 1.6	2.0 x 2.1	1.5 x 1.0

N-Channel Single MOSFET

Package	Part Number	V _{oss} (V)	V _{ess} (V)	I _o (A)	R _{DS(ON)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note
					V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 10 V			
CST3	SSM3K56CT	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
	SSM3K56ACT	\$ 20	+/-8	1.4	-	840	480	300	-	235	-	1	55	
	SSM3K76CT ☆	\$ 20	+/-8	1.4	-	840	480	300	-	235	-	1	55	Low leakage current
VESM	SSM3K36MFV	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
	SSM3K56MFV	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
	SSM3K76MFV ☆	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	Low leakage current
WCSP6C	SSM6K781G	12	+/-8	7	-	124	47.4	23.2	-	18	-	5.4	600	
SSM	SSM3K36FS	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
	SSM3K56FS	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
	SSM3K76FS ☆	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	Low leakage current
ES6	SSM6K217FE	\$ 40	+/-12	1.8	-	-	400	248	218 (@3.6 V) 211 (@4.2 V)	208	195 (@8 V)	1.1	130	
UFM	SSM3K36TU	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
	SSM3K62TU #	\$ 20	+/-8	0.8	432	139	89	68	-	57	-	2	177	
	SSM3K122TU	\$ 20	+/-10	2	-	304	211	161	123	-	-	3.4	195	
	SSM3K121TU	\$ 20	+/-10	3.2	-	140	93	63	48	-	-	5.9	400	
	SSM3K123TU	\$ 20	+/-10	4.2	-	66	43	32	28	-	-	13.6	1010	
	SSM3K127TU	\$ 30	+/-12	2	-	-	286	167	123	-	-	1.5	123	
	SSM3K116TU	\$ 30	+/-12	2.2	-	-	-	135	-	100	-	-	245	
	SSM3K131TU	30	+/-20	6	-	-	-	-	-	41.5	27.6	10.1	450	
	SSM3H137TU	\$ 34	+/-20	2	-	-	-	-	295	280	240	3	119	Built-in Active Clamp Zener
	SSM3K2615TU	\$ 60	+/-20	2	-	-	-	580 (@3.3 V)	440	-	300	6	150	
	SSM3K341TU #	\$ 60	+/-20	6	-	-	-	-	69	51	36	9.3	550	T _{ch} = 175 °C
	SSM3K361TU #	\$ 100	+/-20	3.5	-	-	-	-	-	92	69	3.2	430	T _{ch} = 175 °C
UF6	SSM6K405TU	\$ 20	+/-10	2	-	307	214	164	126	-	-	3.4	195	
	SSM6K404TU	\$ 20	+/-10	3	-	147	100	70	55	-	-	5.9	400	
	SSM6K403TU	\$ 20	+/-10	4.2	-	66	43	32	28	-	-	16.8	1050	
	SSM6K406TU	\$ 30	+/-20	4.4	-	-	-	-	-	38.5	25	12.4	490	
	SSM6K407TU #	\$ 60	+/-20	2	-	-	-	-	440	-	300	6	150	

☆ New Products

AEC-Q101 qualified, \$ With protection Zener diode between gate and source

SOT-23F	TSOP6F	UDFN6B (SOT-1220)
		
2.9 x 2.4	2.9 x 2.8	2.0 x 2.0

Bottom View

N-Channel Single MOSFET

Package	Part Number	V _{BSS} (V)	V _{GSS} (V)	I _D (A)	R _{DS(ON)} max (mΩ)							Q _g typ. (nC)	C _{ISS} typ. (pF)	Note
					V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 10 V			
UDFN6B	SSM6K518NU	\$ 20	+/-8	6	-	108	74	45	-	33	-	3.6	410	
	SSM6K517NU	\$ 30	+12/-8	6	-	-	82	53	-	39.1	-	3.2	310	
	SSM6K504NU	\$ 30	+/-20	9	-	-	-	-	-	26	19.5	4.8	620	
	SSM6K513NU	30	+/-20	15	-	-	-	-	-	12	8.9	7.5	1130	
	SSM6K516NU	\$ 30	+20/-12	6	-	-	-	-	-	64	46	2.5	280	
	SSM6K514NU	40	+/-20	12	-	-	-	-	-	17.3	11.6	7.5	1110	
	SSM6K388NU★	60	+/-20	2	-	-	-	-	-	98	82	TBD	TBD	
	SSM6K389NU★	60	+/-20	2	-	-	-	-	-	200	155	TBD	TBD	
	SSM6K341NU	\$ 60	+/-20	6	-	-	-	-	69	51	36	9.3	550	
	SSM6K387NU★	100	+/-20	2	-	-	-	-	-	200	125	3.6	242	
SOT-23F	SSM6K361NU	\$ 100	+/-20	3.5	-	-	-	-	-	92	69	3.2	430	
	SSM3K344R	\$ 20	+/-8	3	-	232	139	91	-	71	-	2	153	
	SSM3K345R	\$ 20	+/-8	4	-	108	74	45	-	33	-	3.6	410	
	SSM3K324R	\$ 30	+/-12	4	-	-	109	72	-	56	-	2.2	200	
	SSM3K376R #	\$ 30	+12/-8	4	-	-	109	72	-	56	-	2.2	200	
	SSM3K336R	\$ 30	+/-20	3	-	-	-	-	-	140	95	1.7	126	
	SSM3K333R	30	+/-20	6	-	-	-	-	-	42	28	3.4	436	
	SSM3K335R	\$ 30	+/-20	6	-	-	-	-	-	56	38	2.7	340	
	SSM3K347R	\$ 38	+/-20	2	-	-	-	-	480	410	340	2.5	86	Built-in Active Clamp Zener
	SSM3K337R	\$ 38	+/-20	2	-	-	-	-	200	176	150	3	120	Built-in Active Clamp Zener
	SSM3K339R	\$ 40	+/-12	2	-	-	390	238	208 (@3.6 V) 201 (@4.2 V)	198	185 (@8 V)	1.1	130	
	SSM3K357R	\$ 60	+/-12	0.65	-	-	-	2400 (@3 V)	-	1800 (@5 V)	-	1.5	43	Built-in Gate-Drain Zener
	SSM3K2615R	\$ 60	+/-20	2	-	-	-	580 (@3.3 V)	440	-	300	6	150	
	SSM3K388R★	60	+/-20	2	-	-	-	-	-	98	82	TBD	TBD	
	SSM3K389R★	60	+/-20	2	-	-	-	-	-	200	155	TBD	TBD	
	SSM3K318R	\$ 60	+/-20	2.5	-	-	-	-	-	145	107	7	235	
	SSM3K341R #	\$ 60	+/-20	6	-	-	-	-	69	51	36	9.3	550	T _{ch} = 175 °C
	SSM3K387R★	100	+/-20	2	-	-	-	-	-	200	125	3.6	242	
	SSM3K361R #	\$ 100	+/-20	3.5	-	-	-	-	-	92	69	3.2	430	T _{ch} = 175 °C
TSOP6F	SSM6K824R	\$ 20	+/-8	6	-	108	74	45	-	33	-	3.6	410	
	SSM6K818R	30	+/-20	15	-	-	-	-	-	12	8.9	7.5	1130	
	SSM6K804R	40	+/-20	12	-	-	-	-	-	18	12	7.5	1110	
	SSM6K388R★	60	+/-20	2	-	-	-	-	-	98	82	TBD	TBD	
	SSM6K389R★	60	+/-20	2	-	-	-	-	-	200	155	TBD	TBD	
	SSM6K809R #	\$ 60	+/-8	6	-	-	-	-	69	51	36	9.3	550	T _{ch} = 175 °C
	SSM6K387R★	100	+/-20	2	-	-	-	-	-	200	125	3.6	242	
	SSM6K810R #	\$ 100	+/-20	3.5	-	-	-	-	-	92	69	3.2	430	T _{ch} = 175 °C
	SSM6K819R #	\$ 100	+/-20	10	-	-	-	-	-	36.4	25.8	8.5	1110	T _{ch} = 175 °C

★ Under Development (The specification is subject to change without notice.)
 # AEC-Q101 qualified, \$ With protection Zener diode between gate and source

ES6 (SOT-563)	UF6 (SOT-363F)	UDFN6 (SOT-1118)	DFN2020(WF)
			
1.6 x 1.6	2.0 x 2.1	2.0 x 2.0	2.0 x 2.0

Dual MOSFET

Package	Polarity	Part Number	V _{BSS} (V)	V _{SSS} (V)	I _D (A)	R _{DS(ON)} max (mΩ)						Q _g typ. (nC)	C _{ISS} typ. (pF)	Note		
						V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V				V _{GS} = 10 V	
ES6	P-ch x 2	SSM6P41FE	\$	-20	+/-8	-0.72	-	1040	670	440	-	300	-	1.76	110	
		SSM6P56FE	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
		SSM6P76FE ☆	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	Low leakage current
	N-ch x 2	SSM6N36FE	\$	20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
		SSM6N56FE	\$	20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
		SSM6N76FE ☆	\$	20	+/-8	0.8	-	840	480	300	-	235	-	1	55	Low leakage current
	N-ch + P-ch	SSM6L14FE	\$	20	+/-10	0.8	-	600	450	330	-	240	-	2	90	
		SSM6L56FE	\$	20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
				-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
UDFN6	P-ch x 2	SSM6P47NU	\$	-20	+/-8	-4	-	242	170	125	-	95	-	4.6	290	
		SSM6P69NU	\$	-20	+6/-12	-4	-	-	157	76	-	56	45	6.74	480	
		SSM6P49NU	\$	-20	+/-12	-4	-	-	157	76	-	56	45	6.74	480	
	N-ch x 2	SSM6N61NU	\$	20	+/-8	4	-	108	74	45	-	33	-	3.6	410	
		SSM6N55NU	\$	30	+/-20	4	-	-	-	-	-	64	46	2.5	280	
		SSM6N67NU	\$	30	+12/-8	4	-	-	82	53	-	39.1	-	3.2	310	
		SSM6N68NU	\$	30	+12/-8	4	-	-	180	117	-	84	-	1.8	129	
		SSM6N57NU	\$	30	+/-12	4	-	-	82	53	-	39.1	-	3.2	310	
		SSM6N58NU	\$	30	+/-12	4	-	-	180	117	-	84	-	1.8	129	
	N-ch + P-ch	SSM6L61NU	\$	20	+/-8	4	-	108	74	45	-	33	-	3.6	410	
		-20	+/-12	-4	-	-	157	76	-	56	45	6.74	480			
DFN2020 (WF)	N-ch x 2	XSM6N65NW ★ #	\$	30	+20/-12	4	-	-	-	-	64	-	2.5	280	Automotive equipment	
		XSM6N67NW ★ #	\$	30	+12/-8	4	-	-	82	53	-	39.1	-	3.2		310
UF6	P-ch x 2	SSM6P39TU	\$	-20	+/-8	-1.5	-	-	430	294	213	-	-	6.4	250	
		SSM6P40TU	\$	-30	+/-20	-1.4	-	-	-	-	403	-	226	2.9	120	
	N-ch x 2	SSM6N36TU	\$	20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
		SSM6N62TU	\$	20	+/-8	0.8	456	173	120	98	-	85	-	2	177	
		SSM6N39TU	\$	20	+/-10	1.6	-	247	190	139	119	-	-	7.5	260	
		SSM6N24TU	\$	30	+/-12	0.5	-	-	-	180	-	145	-	-	245	
		SSM6N40TU	\$	30	+/-20	1.6	-	-	-	-	182	-	122	5.1	180	
	N-ch + P-ch	SSM6L39TU	\$	20	+/-10	1.6	-	247	190	139	119	-	-	7.5	260	
				-20	+/-8	-1.5	-	-	430	294	213	-	-	6.4	250	
		SSM6L12TU	\$	30	+/-12	0.5	-	-	-	180	-	145	-	-	245	
				-20	+/-12	-0.5	-	-	-	430	260	-	-	-	218	
SSM6L40TU		\$	30	+/-20	1.6	-	-	-	-	182	-	122	5.1	180		
			-30	+/-20	-1.4	-	-	-	-	403	-	226	2.9	120		

☆ New Products, ★ Under Development (The specification is subject to change without notice.)
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

US6 (SOT-363)	TSOP6F	TCSP6A- 172101	TCSPAC- 153001	TCSPED- 302701	TCSPAG- 341501
					
Bottom View	Bottom View	Bottom View	Bottom View	Bottom View	Bottom View
2.0 x 2.1	2.9 x 2.8	2.14 x 1.67	2.98 x 1.49	3.0 x 2.74	3.37 x 1.47

Dual MOSFET

Package	Polarity	Part Number	V _{DSS} or V _{SSS} (V)	V _{GSS} (V)	I _D or I _S (A)	R _{DS(ON)} max or R _{SS(ON)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note
						V _{Gs} = 1.2 V	V _{Gs} = 1.5 V	V _{Gs} = 1.8 V	V _{Gs} = 2.5 V	V _{Gs} = 4 V	V _{Gs} = 4.5 V	V _{Gs} = 10 V			
US6	N-ch x 2	SSM6N43FU	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
TSOP6F	N-ch x 2	SSM6N357R	\$ 60	+/-12	0.65	-	-	-	2400 (@3 V)	-	1800 (@5 V)	-	1.5	43	Built-in Gate-Drain Zener
		SSM6N815R	\$ 100	+/-20	2	-	-	-	-	180	142	103	3.1	290	
		SSM6N813R	# \$ 100	+/-20	3.5	-	-	-	-	-	154	112	3.6	242	T _{ch} = 175 °C
	P-ch x 2	SSM6P816R	\$ -20	+/-10	-6	-	-	52.3	38.8	-	30.1	-	16.6	1030	
	N-ch + P-ch	SSM6L807R	\$	30	+/-12	4	-	-	82	53	-	39.1	-	3.2	310
				-20	+/-12	-4	-	-	157	76	-	56	45	6.74	480
		SSM6L820R	# \$	30	+12/-8	4	-	-	82	53	-	39.1	-	3.2	310
				-20	+6/-12	-4	-	-	157	76	-	56	45	6.7	480
TCSP6A-172101	N-ch x 2	SSM6N951L	\$ 12	+/-8	8	-	-	-	10	5.5 (@3.8 V)	5.1	-	26	-	Drain common
TCSPAC-153001	N-ch x 2	SSM10N954L	\$ 12	+/-8	13.5	-	-	-	6.1	2.85 (@3.8 V)	2.75	-	25	-	Drain common
TCSPED-302701	N-ch x 2	SSM14N956L ☆	\$ 12	+/-8	20	-	-	-	3.2	1.5 (@3.8 V)	1.35	-	76	-	Drain common
TCSPAG-341501	N-ch x 2	SSM10N961L ☆	\$ 30	+/-20	14	-	-	-	-	-	17.6	12.8	8.8	-	Drain common

☆ New Products
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

■ Less than 500mA Series MOSFETs (Standard Type)

Package Dimensions (unit: mm)

CST3C	CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	UFM (SOT-323F)	USM (SOT-323)	S-Mini (SOT-346)
Bottom View 	Bottom View 					
0.8 x 0.6	1.0 x 0.6	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.0 x 2.1	2.9 x 2.5

P-Channel Single MOSFET

Package	Part Number	V _{DS} (V)	V _{GS} (V)	I _D (A)	R _{DS(ON)} max (Ω)						Note	
					V _{GS} = -1.2 V	V _{GS} = -1.5 V	V _{GS} = -1.8 V	V _{GS} = -2.5 V	V _{GS} = -4 V	V _{GS} = -4.5 V		V _{GS} = -10 V
CST3C	SSM3J35CTC	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	
	SSM3J78CTC ☆	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	Low leakage current
CST3	SSM3J35CT	\$ -20	+/-10	-0.1	44	22	-	11	8	-	-	
	SSM3J16CT ●	\$ -20	+/-10	-0.1	-	45	-	12	8	-	-	⇒ SSM3J35CT
	SSM3J15CT	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	
VESM	SSM3J35MFV	\$ -20	+/-10	-0.1	44	22	-	11	8	-	-	⇒ SSM3J35AMFV
	SSM3J36MFV	\$ -20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	⇒ SSM3J56MFV
	SSM3J35AMFV	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	
	SSM3J78MFV ☆	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	Low leakage current
	SSM3J15FV	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	
SSM	SSM3J35FS	\$ -20	+/-10	-0.1	44	22	-	11	8	-	-	⇒ SSM3J35AFS
	SSM3J35AFS	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	
	SSM3J78FS ☆	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	Low leakage current
	SSM3J36FS	\$ -20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	
	SSM3J15FS	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	
UFM	SSM3J36TU	\$ -20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	
USM	SSM3J15FU	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	
S-Mini	SSM3J15F	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	
	2SJ305	\$ -30	+/-20	-0.2	-	-	-	4	-	-	-	
	SSM3J168F #	\$ -60	+10/-20	-0.4	-	-	-	-	2	1.9	1.55	

☆ New Products

● Recommended Another New Product

AEC-Q101 qualified, \$ With protection Zener diode between gate and source

CST3C	CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	SOT23 (SOT-23)	S-Mini (SOT-346)
Bottom View	Bottom View					
0.8 x 0.6	1.0 x 0.6	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.4	2.9 x 2.5

N-Channel Single MOSFET

Package	Part Number	V _{DS} (V)	V _{GS} (V)	I _D (A)	R _{DS(ON)} max (Ω)								Note
					V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 5 V	V _{GS} = 10 V	
CST3C	SSM3K35CTC	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
	SSM3K78CTC ☆	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
	SSM3K15ACTC	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79CTC ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
CST3	SSM3K72CTC	\$ 60	+/-20	0.15	-	-	-	5.7 (typ.)	-	4.7	4.4	3.9	
	SSM3K16CT	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
	SSM3K35CT	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	
	SSM3K37CT	\$ 20	+/-10	0.2	-	5.6	4.05	3.02	-	2.2	-	-	
	SSM3K77CT ☆	\$ 20	+/-10	0.2	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
	SSM3K15CT ●	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM3K15ACT
	SSM3K15ACT	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79CT ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
VESM	SSM3K72KCT	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	
	SSM3K16FV	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
	SSM3K35MFV	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM3K35AMFV
	SSM3K37MFV	\$ 20	+/-10	0.25	-	5.6	4.05	3.02	-	2.2	-	-	
	SSM3K77MFV ☆	\$ 20	+/-10	0.25	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
	SSM3K35AMFV	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
	SSM3K78MFV ☆	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
	SSM3K15AMFV	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
SSM	SSM3K79MFV ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K44MFV	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
	SSM3K16FS	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	⇒ SSM3K37FS
	SSM3K35FS	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM3K35AFS
	SSM3K37FS	\$ 20	+/-10	0.2	-	5.6	4.05	3.02	-	2.2	-	-	
	SSM3K77FS ☆	\$ 20	+/-10	0.2	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
	SSM3K35AFS	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
	SSM3K78FS ☆	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
	SSM3K15FS ●	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM3K15AFS
	SSM3K44FS	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
	SSM3K15AFS	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79FS ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
USM	SSM3K72CFV	\$ 60	+/-20	0.17	-	-	-	-	-	4.7	4.4	3.9	
	SSM3K72KFS #	\$ 60	+/-20	0.3	-	-	-	-	-	1.75	1.65	1.5	
	SSM3K16FU	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
	SSM3K15FU	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM3K15AFU
	SSM3K15AFU	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79FU ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K48FU ●	\$ 30	+/-20	0.1	-	-	-	5.4	3.2	-	-	-	⇒ SSM3K15AFU
	SSM3K09FU	\$ 30	+/-20	0.4	-	-	-	1.7 (@3.3V)	1.2	-	-	0.7	
SOT23	SSM3K17FU	\$ 50	+/-7	0.1	-	-	-	-	-	4.7	4.4	3.9	
	SSM3K7002CFU	\$ 60	+/-20	0.17	-	-	-	-	-	1.75	1.65	1.5	
	SSM3K7002KFU #	\$ 60	+/-20	0.4	-	-	-	-	-	4.7	4.4	3.9	
	T2N7002AK	\$ 60	+/-20	0.2	-	-	-	-	-	1.75	1.65	1.5	
S-Mini	T2N7002BK	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	
	SSM3K15F	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
	2SK2009	\$ 30	+/-20	0.2	-	-	-	2	-	-	-	-	
	SSM3K7002KF	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	

☆ New Products

● Recommended Another New Product, # AEC-Q101 qualified, \$ With protection Zener diode between gate and source

ESV (SOT-553)	ES6 (SOT-563)	USV (SOT-353)	UF6 (SOT-363F)
			
1.6 x 1.6	1.6 x 1.6	2.0 x 2.1	2.0 x 2.1

Dual MOSFET

Package	Polarity	Part Number	V _{oss} (V)	V _{ess} (V)	I _D (A)	R _{DS(ON)} max (Ω)								Note
						V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 5 V	V _{GS} = 10 V	
ESV	P-ch x 2	SSM5P16FE	\$ -20	+/-10	-0.1	-	45	-	12	8	-	-	-	
	N-ch x 2	SSM5N16FE	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM5N15FE	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
ES6	P-ch x 2	SSM6P35FE	\$ -20	+/-10	-0.1	44	22	-	11	8	-	-	-	⇒ SSM6P35AFE
		SSM6P35AFE	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	
		SSM6P78FE ☆	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	Low leakage current
		SSM6P36FE	\$ -20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	-	
		SSM6P15FE	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	-	
	N-ch x 2	SSM6N16FE	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM6N35FE	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM6N35AFE
		SSM6N37FE	\$ 20	+/-10	0.25	-	5.6	4.05	3.02	-	2.2	-	-	
		SSM6N77FE ☆	\$ 20	+/-10	0.25	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
		SSM6N35AFE	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
		SSM6N78FE ☆	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
		SSM6N44FE	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
		SSM6N15AFE	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
		SSM6N79FE ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
		SSM6N7002BFE	\$ 60	+/-20	0.2	-	-	-	-	-	3.3	2.6	2.1	
	N-ch + P-ch	SSM6L35FE	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	
			-20	+/-10	-0.1	44	22	-	11	8	-	-	-	
		SSM6L36FE	\$ 20	+/-10	0.5	-	1.52	1.14	0.85	-	0.66	0.63	-	
			-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	-	
USV	P-ch x 2	SSM5P15FU	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	-	
	N-ch x 2	SSM5N16FU	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM5N15FU	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
UF6	P-ch x 2	SSM6P36TU	\$ -20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	-	
	N-ch + P-ch	SSM6L36TU	\$ 20	+/-10	0.5	-	1.52	1.14	0.85	-	0.66	0.63	-	
			-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	-	

☆ New Products
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

US6
(SOT-363)

2.0 x 2.1

Dual MOSFET

Package	Polarity	Part Number	V _{DSS} (V)	V _{GSS} (V)	I _D (A)	R _{DS(ON)} max (Ω)								Note
						V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 5 V	V _{GS} = 10 V	
US6	P-ch x 2	SSM6P35FU	\$ -20	+/-10	-0.1	44	22	-	11	8	-	-	-	⇒ SSM6P35AFU
		SSM6P35AFU	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	
		SSM6P78FU ☆	\$ -20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	Low leakage current
		SSM6P15FU	\$ -30	+/-20	-0.1	-	-	-	32	12	-	-	-	
	N-ch x 2	SSM6N16FU	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM6N35FU	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM6N35AFU
		SSM6N35AFU	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
		SSM6N78FU ☆	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
		SSM6N37FU	\$ 20	+/-10	0.25	-	5.6	4.05	3.02	-	2.2	-	-	
		SSM6N77FU ☆	\$ 20	+/-10	0.25	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
		SSM6N48FU ●	\$ 30	+/-20	0.1	-	-	-	5.4	3.2	-	-	-	⇒ SSM6N15AFU
		SSM6N44FU	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
		SSM6N15FU ●	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM6N15AFU
		SSM6N15AFU	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
		SSM6N79FU ☆	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
		SSM6N09FU	\$ 30	+/-20	0.4	-	-	-	1.7 (@3.3V)	1.2	-	-	0.7	
		SSM6N17FU	\$ 50	+/-7	0.1	-	-	-	40	20	-	-	-	
		SSM6N7002CFU	\$ 60	+/-20	0.17	-	-	-	-	-	4.7	4.4	3.9	
		SSM6N7002KFU #	\$ 60	+/-20	0.3	-	-	-	-	-	1.75	1.65	1.5	
	N-ch + P-ch	SSM6L35FU	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	
			-20	+/-10	-0.1	44	22	-	11	8	-	-	-	
		SSM6L09FU ●	\$ 30	+/-20	0.4	-	-	-	1.7 (@3.3V)	1.2	-	-	0.7	⇒ SSM6L40TU
		-30	+/-20	-0.2	-	-	-	6 (@3.3V)	4.2	-	-	2.7		

☆ New Products

● Recommended Another New Product, # AEC-Q101 qualified, \$ With protection Zener diode between gate and source

MOSFET with Diode

Package Dimensions (unit: mm)

ESV (SOT-553)	UFV (SOT-353F)	UDFN6 (SOT-1118)
		
1.6 x 1.6	2.0 x 2.1	2.0 x 2.0

Package	Polarity	Part Number	V _{DSS} (V)	V _{GSS} (V)	I _O (A)	MOSFET								Diode				Note
						R _{DS(ON)} max (mΩ)						C _{iss} typ. (pF)	V _R (V)	I _O (A)	V _F max (V)			
						V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 5 V				V _{GS} = 10 V	@I _F (A)		
ESV	P-ch + SBD	SSM5G06FE	\$ -20	+/-10	-0.1	45000	-	12000	8000	-	-	-	11	12	0.1	0.5	0.1	
	N-ch + SBD	SSM5H06FE	\$ 20	+/-10	0.1	15000	-	4000	3000	-	-	-	9.3	12	0.1	0.5	0.1	
UFV	P-ch + SBD	SSM5G02TU	\$ -12	+/-12	-1	-	-	240	160	-	-	-	310	12	0.5	0.43	0.5	
		SSM5G09TU	\$ -12	+/-8	-1.5	-	-	200	130	-	-	-	550	12	0.5	0.43	0.5	
		SSM5G11TU	\$ -30	+/-20	-1.4	-	-	-	403	-	-	226	120	30(¥)	0.7(¥¥)	0.44	0.7(¥¥)	
	N-ch + SBD	SSM5H16TU	\$ 30	+/-12	1.9	-	296	177	133	-	-	-	123	30	0.8	0.55	0.8	
	N-ch + Switching Diode	SSM5H90ATU	\$ 20	+/-10	2.4	-	-	89	65	-	-	-	200	80	0.1	1.2	0.1	
UDFN6	P-ch + SBD	SSM6G18NU	\$ -20	+/-8	-2	261	185	143	-	112	-	-	270	30	1	0.58	1	
	N-ch + SBD	SSM6H19NU	\$ 40	+/-12	2	-	390	238	208 @3.6V 201 @4.2V	198	-	185 @8V	130	40	0.5	0.57	0.5	

\$ With protection Zener diode between gate and source, ¥ V_{RRM}, ¥¥ I_{F(AV)}

1 MOSFETs

2 Tr./BRTs

3 Diodes

4 Power Management ICs

5 Linear ICs

6 Sensors

7 General Purpose Logic ICs

8 RF Devices

9 Packages

Part Naming Conventions

Small-Signal MOSFET SSM / XSM Series

Ex.) SSM 3 K 329 — R
 ① ② ③ ④ ⑤ ⑥

① Small-Signal MOSFET

SSM : Initial of “Small-Signal MOSFET”

XSM : Initial of “Automotive Small-Signal MOSFET”

② Pin count

③ Polarity and internal configuration

K : N-channel, single

J : P-channel, single

N : N-channel, dual

P : P-channel, dual

L : N-channel and P-channel (dual)

E : N-channel and P-channel (pre-wired as a load switch)

H : N-channel and SBD (or Switching diode)

G : P-channel and SBD

④ Serial number of the products

⑤ There may be a symbol that indicates chip change etc.

⑥ Package

3-pin	F: S-Mini	5-pin	F: SMV
	FU: USM		FU: USV
	FS: SSM		FE: ESV
	FV: VESM		TU: UFV
	TU: UFM	6-pin	G: WCSP6C
	CT: CST3		L: Chip LGA
	CTB: CST3B		(TCSP6A-172101)
	CTC: CST3C		R: TSOP6F
	R: SOT-23F		FU: US6
			FE: ES6
			TU: UF6
			NU: UDFN6 / UDFN6B
			NW: DFN2020(WF)
10-pin	L: Chip LGA		(TCSPAC-153001)
			(TCSPAG-341501)
14-pin	L: Chip LGA		(TCSPED-302701)

2. Bipolar Transistors

■ General-Purpose Transistors

Package Dimensions (unit: mm)

Classification	$ V_{CE0} $ (V)	$ I_C $ (mA)	CST3 (SOT-883)		VESM (SOT-723)		SSM (SOT-416)	
			Bottom View					
			1.0 x 0.6		1.2 x 1.2		1.6 x 1.6	
			Part Number					
General Purpose	50	100	NPN	PNP	NPN	PNP	NPN	PNP
			2SC6026CT	2SA2154CT				
					2SC6026MFV #	2SA2154MFV #	2SC4738 #	2SA1832 #

Classification	$ V_{ce0} $ (V)	$ I_c $ (mA)	USM (SOT-323)		UFM (SOT-323F)		S-Mini (SOT-346)		SOT23 (SOT-23)		SOT-23F	
			 2.0 x 2.1		 2.0 x 2.1		 2.9 x 2.5		 2.9 x 2.4		 2.9 x 2.4	
			Part Number									
			NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP
General Purpose	30	500		2SA1588 #				2SA1182 #				
	50	150	2SC4116 #	2SA1586 #			2SC2712 #	2SA1162 #	TBC847	TBC857		
			TTC4116FU	TTA1586FU								
									TMBT3904	TMBT3906		
	50	500					2SC3325 #	2SA1313 #				
						TTC1949						
45							TTA1713					
Low Noise	120	100	2SC4117 #	2SA1587 #			2SC2713 #	2SA1163 #				
Low Saturation	15	800					2SA1362 #					
Muting	20	300	2SC4213				2SC3326 #					
High Current	20	2500				2SA2215 #						TTA502 # ☆
	25	800					2SC3265 #	2SA1298 #				
	50	1000			2SC6135 #						TTC500 # ☆	TTA500 # ☆
	50	1700				2SA2195 #						
	50	2000										TTA501 # ☆
	50	2500			2SC6100 #						TTC501 # ☆	
	120	1000									TTC502 # ☆	
High Breakdown	300	100					2SA1721					

☆ New Products
AEC-Q101 qualified

Classification	$ V_{CE0} $ (V)	$ I_C $ (mA)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)			
			 1.6 x 1.6	 2.0 x 2.1	 2.9 x 2.8			
			Part Number					
			Complementary	NPN x 2	PNP x 2	NPN x 2	PNP x 2	Complementary
General Purpose	50	150	HN4B01JE 	2SC4944 	2SA1873 	2SC4207 	2SA1618 	
					HN4A56JU 			
Low Noise	120	100				HN4C06J 	HN4A06J 	HN4B06J 
						HN4C51J 	HN4A51J 	

Classification	$ V_{CE0} $ (V)	$ I_C $ (mA)	ES6 (SOT-563)			US6 (SOT-363)			SM6 (SOT-26)		
			 1.6 x 1.6			 2.0 x 2.1			 2.9 x 2.8		
			Part Number								
			NPN x 2	PNP x 2	Complementary	NPN x 2	PNP x 2	Complementary	NPN x 2	PNP x 2	Complementary
General Purpose	50	150									
											
	50	500									
High Current	15	800									
Muting	20	300									

AEC-Q101 qualified

Bipolar transistor with Diode

Package Dimensions (unit: mm)

SM6

(SOT-26)



2.9 x 2.8

Package	Polarity	Part Number	V _{CEO} (V)	I _C (A)	PNP transistor			Switching Diode			Note	
					h _{FE}	V _{CE(sat)} max (V) I _C = -10 mA, I _B = -1 mA	C _{ob} typ. (pF)	V _R (V)	I _O (A)	V _F max (V) @ I _F (A)		
					V _{CE} = -6 V, I _C = -2 mA							
SM6	PNP + Switching Diode	HN2E04F	-120	-0.1	200 to 700	-0.3	4	80	0.1	1.2	0.1	

1 MOSFETs

2 Tr./BRTs

3 Diodes

4 Power Management ICs

5 Linear ICs

6 Sensors

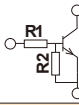
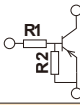
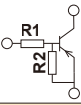
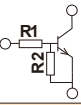
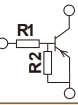
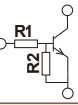
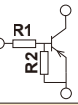
7 General Purpose Logic ICs

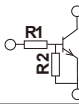
8 RF Devices

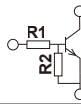
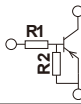
9 Packages

■ Bias Resistor Built-in Transistors (BRTs)

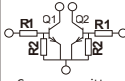
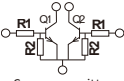
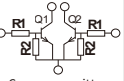
Package Dimensions (unit: mm)

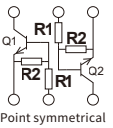
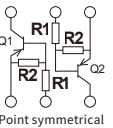
		V _{ceo} (V)	I _c (mA)	Resistance	VESM (SOT-723)		SSM (SOT-416)		USM (SOT-323)		S-Mini (SOT-346)			
					 1.2 x 1.2		 1.6 x 1.6		 2.0 x 2.1		 2.9 x 2.5			
					 		 		 		 			
					R1 typ. (kΩ)	R2 typ. (kΩ)	NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP
					Part Number									
50 100	4.7	4.7	RN1101MFV #	RN2101MFV #	RN1101 #	RN2101 #	RN1301 #	RN2301 #	RN1401 #	RN2401 #				
	10	10	RN1102MFV #	RN2102MFV #	RN1102 #	RN2102 #	RN1302 #	RN2302 #	RN1402 #	RN2402 #				
	22	22	RN1103MFV #	RN2103MFV #	RN1103 #	RN2103 #	RN1303 #	RN2303 #	RN1403 #	RN2403 #				
	47	47	RN1104MFV #	RN2104MFV #	RN1104 #	RN2104 #	RN1304 #	RN2304 #	RN1404 #	RN2404 #				
	2.2	47	RN1105MFV #	RN2105MFV #	RN1105 #	RN2105 #	RN1305 #	RN2305 #	RN1405 #	RN2405 #				
	4.7	47	RN1106MFV #	RN2106MFV #	RN1106 #	RN2106 #	RN1306 #	RN2306 #	RN1406 #	RN2406 #				
	10	47	RN1107MFV #	RN2107MFV #	RN1107 #	RN2107 #	RN1307 #	RN2307 #	RN1407 #	RN2407 #				
	22	47	RN1108MFV #	RN2108MFV #	RN1108 #	RN2108 #	RN1308 #	RN2308 #	RN1408 #	RN2408 #				
	47	22	RN1109MFV #	RN2109MFV #	RN1109 #	RN2109 #	RN1309 #	RN2309 #	RN1409 #	RN2409 #				
	4.7	-	RN1110MFV #	RN2110MFV #	RN1110 #	RN2110 #	RN1310 #	RN2310 #	RN1410 #	RN2410 #				
	10	-	RN1111MFV #	RN2111MFV #	RN1111 #	RN2111 #	RN1311 #	RN2311 #	RN1411 #	RN2411 #				
	22	-	RN1112MFV #	RN2112MFV #	RN1112 #	RN2112 #	RN1312 #	RN2312 #	RN1412 #	RN2412 #				
	47	-	RN1113MFV #	RN2113MFV #	RN1113 #	RN2113 #	RN1313 #	RN2313 #	RN1413 #	RN2413 #				
	1	10	RN1114MFV #	RN2114MFV #	RN1114	RN2114	RN1314	-	RN1414	RN2414				
	2.2	10	RN1115MFV #	RN2115MFV #	RN1115 #	RN2115 #	RN1315 #	RN2315 #	RN1415 #	RN2415 #				
	4.7	10	RN1116MFV #	RN2116MFV #	RN1116 #	RN2116 #	RN1316 #	RN2316 #	RN1416 #	RN2416 #				
	10	4.7	RN1117MFV #	RN2117MFV #	RN1117	RN2117	RN1317	RN2317 #	RN1417 #	RN2417 #				
	47	10	RN1118MFV #	-	RN1118	-	RN1318	RN2318	RN1418 #	RN2418 #				
	1	-	RN1119MFV #	RN2119MFV #	-	-	-	-	-	-				
	100	100	RN1130MFV #	RN2130MFV #	-	-	-	-	-	-				
	100	-	RN1131MFV #	RN2131MFV #	-	-	-	-	-	-				
	200	-	RN1132MFV #	RN2132MFV #	-	-	-	-	-	-				

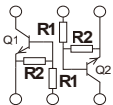
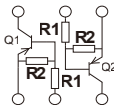
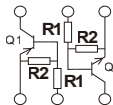
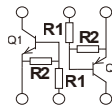
V _{ce1} (V)		I _{c1} (mA)		Resistance		SOT23 (SOT-23)	
							
						2.9 x 2.4	
							
R1 typ. (kΩ)	R2 typ. (kΩ)	NPN		PNP			
Part Number							
50	100	4.7	4.7	TDTC143E	TDTA143E		
		10	10	TDTC144E	TDTA144E		
		22	22	TDTC124E	TDTA124E		
		47	47	TDTC144E	TDTA144E		
		2.2	47	TDTC123J	TDTA123J		
		4.7	47	TDTC143Z	TDTA143Z		
		10	47	TDTC144Y	TDTA144Y		

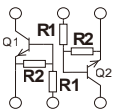
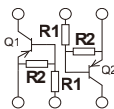
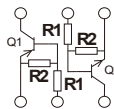
	V _{ceo} (V)	I _c (mA)	Resistance		S-Mini (SOT-346)	
					 2.9 x 2.5	
					 	
			R1 typ. (kΩ)	R2 typ. (kΩ)	NPN	PNP
50	800	1	1	RN1421	RN2421	
		2.2	2.2	RN1422	RN2422	
		4.7	4.7	RN1423	RN2423	
		10	10	RN1424	RN2424	
		0.47	10	RN1425	RN2425	
		1	10	RN1426	RN2426	
		2.2	10	RN1427	RN2427	

AEC-Q101 qualified

		V_{ce0} (V)	I_c (mA)	Resistance		ESV (SOT-553)		USV (SOT-353)		SMV (SOT-25)	
						 1.6 x 1.6		 2.0 x 2.1		 2.9 x 2.8	
						 Common emitter		 Common emitter		 Common emitter	
						NPN x 2		PNP x 2		NPN x 2	
				R1 typ. (kΩ)	R2 typ. (kΩ)	Part Number					
50	100	4.7	4.7	RN1701JE	RN2701JE	RN1701 #	RN2701 #	RN1501	RN2501		
		10	10	RN1702JE	RN2702JE	RN1702 #	RN2702 #	RN1502	RN2502		
		22	22	RN1703JE	RN2703JE	RN1703 #	RN2703 #	RN1503	RN2503		
		47	47	RN1704JE	RN2704JE	RN1704 #	RN2704 #	RN1504	RN2504		
		2.2	47	RN1705JE	RN2705JE	RN1705 #	RN2705 #	RN1505	RN2505		
		4.7	47	RN1706JE	RN2706JE	RN1706 #	RN2706 #	RN1506	RN2506		
		10	47	RN1707JE	RN2707JE	RN1707 #	RN2707 #	RN1507	RN2507		
		22	47	RN1708JE	RN2708JE	RN1708 #	RN2708 #	RN1508	-		
		47	22	RN1709JE	RN2709JE	RN1709 #	RN2709 #	RN1509	-		
		4.7	-	RN1710JE	RN2710JE	RN1710 #	RN2710 #	RN1510	RN2510		
		10	-	RN1711JE	RN2711JE	RN1711 #	RN2711 #	RN1511	RN2511		
		22	-	-	RN2712JE	-	-	-	-		
		47	-	-	RN2713JE	-	-	-	-		

	V_{ce0} (V)	I_{c0} (mA)	Resistance		ES6 (SOT-563)			
					 1.6 x 1.6			
					 Point symmetrical			
					 Point symmetrical			
			R1 typ. (k Ω)	R2 typ. (k Ω)	Part Number			
50	100	4.7	4.7		NPN x 2	PNP x 2	PNP + NPN	NPN + PNP
		10	10		Part Number			
		22	22		RN1901FE #	RN2901FE #	RN4901FE #	RN4981FE #
		47	47		RN1902FE #	RN2902FE #	RN4902FE #	RN4982FE #
		2.2	47		RN1903FE #	RN2903FE #	RN4903FE #	RN4983FE #
		4.7	47		RN1904FE #	RN2904FE #	RN4904FE #	RN4984FE #
		2.2	47		RN1905FE #	RN2905FE #	RN4905FE #	RN4985FE #
		4.7	47		RN1906FE #	RN2906FE #	RN4906FE #	RN4986FE #
		10	47		RN1907FE #	RN2907FE #	RN4907FE #	RN4987FE #
		22	47		RN1908FE #	RN2908FE #	RN4908FE #	RN4988FE #
		47	22		RN1909FE #	RN2909FE #	RN4909FE #	RN4989FE #
		4.7	-		RN1910FE #	RN2910FE #	RN4910FE #	RN4990FE #
		10	-		RN1911FE #	RN2911FE #	RN4911FE #	RN4991FE #

			US6 (SOT-363)				
							
			2.0 x 2.1				
			   				
V _{ce(s)} (V)	I _c (mA)	Resistance					
		R1 typ. (kΩ)	R2 typ. (kΩ)	Part Number			
50	100	4.7	4.7	RN1901 #	RN2901 #	RN4901 #	RN4981 #
		10	10	RN1902 #	RN2902 #	RN4902 #	RN4982 #
		22	22	RN1903 #	RN2903 #	RN4903 #	RN4983 #
		47	47	RN1904 #	RN2904 #	RN4904 #	RN4984 #
		2.2	47	RN1905 #	RN2905 #	RN4905 #	RN4985 #
		4.7	47	RN1906 #	RN2906 #	RN4906 #	RN4986 #
		10	47	RN1907 #	RN2907 #	RN4907 #	RN4987 #
		22	47	RN1908 #	RN2908 #	RN4908 #	RN4988 #
		47	22	RN1909 #	RN2909 #	RN4909 #	RN4989 #
		4.7	-	RN1910 #	RN2910 #	RN4910 #	RN4990
		10	-	RN1911 #	RN2911 #	RN4911 #	-
		47 / 2.2*	47	-	-	-	RN49A2

[Vce] (V)	[Ic] (mA)	Resistance		SM6 (SOT-26)			
							
				2.9 x 2.8			
				 Point symmetrical	 Point symmetrical	 Point symmetrical	
R1 typ. (kΩ)	R2 typ. (kΩ)	NPN x 2	PNP x 2	PNP + NPN	Part Number		
50	100	4.7	4.7	RN1601	RN2601	RN4601	
		10	10	RN1602	RN2602	RN4602	
		22	22	RN1603	RN2603	RN4603	
		47	47	RN1604	RN2604	RN4604	
		2.2	47	RN1605	RN2605	RN4605	
		4.7	47	RN1606	RN2606	RN4606	
		10	47	RN1607	RN2607	RN4607	
		22	47	RN1608	RN2608	RN4608	
		47	22	RN1609	-	RN4609	
		4.7	-	RN1610	RN2610	RN4610	
		10	-	RN1611	-	RN4611	
		22	-	-	-	RN4612	

* Q1/Q2
AEC-Q101 qualified

3. Diodes

■ Schottky Barrier Diodes (SBDs)

Package Dimensions (unit: mm)

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					CST2 (SOD-882)	CST2B	CST2C (SOD-963)	USC (SOD-323)	US2H (SOD-323HE)	UFV (SOT-353F)		
								Bottom View	Bottom View	Bottom View					
	V _R / V _{RM} * (V)	I _O (A)	V _F			I _R max (μA)		C _t typ. (pF)							
High-V _F and I _O	60	2	0.52	0.59	2	70	60	300	1.0 x 0.6	1.2 x 0.8	1.6 x 0.8	2.5 x 1.25	2.5 x 1.4	2.0 x 2.1	
			0.46	0.53	2	650	60	290					CUHS20F60		
		1.5	0.66	0.73	1.5	50	60	130					CUHS15F60		
			0.6	0.67	1.5	450	60	130					CUHS15S60		
	40	1	0.56	0.62	1	40	60	130					CUHS10F60		
			0.47	0.54	2	60	40	300					CUHS20F40		
			0.4	0.47	2	300	40	290					CUHS20S40		
			0.45	0.51	1.5	200	40	170					CUHS15S40		
		1.5	0.57	0.63	1.5	50	40	130					CUHS15F40		
			0.59	0.64	1.5	25	40	130			CCS15F40				
			1	to 0.63	to 0.7	1	20	40	74		CBS10F40		CUS10F40		
			0.5	0.74	0.81	0.5	15	40	28	CTS05F40			CUS05F40		
		40*	1.5	0.47	0.55	1.5	200	40	170			CCS15S40	CUS15S40		
			1	to 0.48	to 0.55	1	150	40	120		CBS10S40		CUS10S40		
			0.5	0.56	0.6	0.5	50	40	42	CTS05S40			CUS05S40		
			30	2	0.4	0.47	2	60	30	380					CUHS20F30
	0.34	0.41			2	500	30	390					CUHS20S30		
	0.46	0.52			1.5	50	30	170					CUHS15F30		
	1.5	0.37		0.43	1.5	500	30	200					CUHS15S30		
		1		0.47	0.57	1	50	30	120						
				0.43	0.5	1	50	30	170				CUS10F30		
	0.8			0.4	0.45	0.8	50	30	170				CUS08F30		
	0.5	0.38		0.45	0.5	50	30	to 120		CBS05F30		CUS05F30			
		0.38		0.47	0.5	100	20	-				CUS551V30			
	30*	1.5	0.39	-	1.5	500	30	200			CCS15S30	CUS15S30			
		1	to 0.39	0.45	1	500	30	135		CBS10S30		CUS10S30			
		0.5	0.41	0.47	0.5	300	30	55	CTS05S30			CUS05S30			

1 MOSFETS

2 Tr./BJT's

3 Diodes

4 Power Management ICs

5 Linear ICs

6 Sensors

7 General Purpose Logic ICs

8 RF Devices

9 Packages

Schottky Barrier Diodes (SBDs)

Package Dimensions (unit: mm)

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						CL2E	CST2 (SOD-882)	SOD-923	ESC (SOD-523)	USC (SOD-323)
									Bottom View	Bottom View			
	V _R (V)	I _O (A)	V _F			I _R max (μA)		C _t typ. (pF)					
			typ. (V)	max (V)	@I _F (A)		@V _R (V)		1.0 x 0.6	1.0 x 0.6	1.0 x 0.6	1.6 x 0.8	2.5 x 1.25
Low-I _R High-Speed	40	1	0.52	0.57	1	25	40	130	CLS10F40				
	20	0.05	0.5	0.55	0.05	0.5	20	3.9		1SS413CT	1SS413	1SS405 #	1SS406 #

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						S-Mini (SOT-346)	US6 (SOT-363)
										
	V _R (V)	I _O (A)	V _F			I _R		C _t		
			typ. (V)	max (V)	@I _F (A)	max (μA)	@V _R (V)	typ. (pF)	2.9 x 2.5	2.0 x 2.1
Low-I _R High-Speed	20	0.05	0.5	0.55	0.05	0.5	20	3.9		HN2S03FU 
	10	0.05	0.63	1	0.05	0.5	10	3.2		

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						SL2 (SOD-962)	CST2 (SOD-882)	SOD-923	ESC (SOD-523)	USC (SOD-323)
									Bottom View 	Bottom View 			
	V _R (V)	I _O (A)	V _F			I _R max (μA)		C _t typ. (pF)	0.62 x 0.32	1.0 x 0.6	1.0 x 0.6	1.6 x 0.8	2.5 x 1.25
Standard	40	0.1	0.54	0.6	0.1	5	40	11				CES388 #	CUS357 #
			0.56	0.62	0.1	5	40	15		1SS417CT	1SS417		
	30	0.2	0.52	0.6	0.2	5	30	to 17		CTS520		CES520 #	CUS520 #
			0.45	0.5	0.2	30	30	to 26		CTS521		CES521	CUS521 #
			0.38	0.5	0.1	50	30	15		1SS416CT	1SS416		
		0.1	0.51	0.62	0.1	0.7	30	8.2	DSR01S30SL				
			0.41	0.5	0.1	50	30	9.3	DSF01S30SL				
			20	0.3	0.38	0.45	0.3	50	20	46			
	0.2	0.42		0.5	0.2	50	20	20				1SS424	
	10	0.1	0.35	0.5	0.1	20	10	20				1SS389 #	1SS367 #

AEC-Q101 qualified

■ Schottky Barrier Diodes (SBDs)

Package Dimensions (unit: mm)

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	S-Mini (SOT-346)	SOT23 (SOT-23)	
	V _R (V)	I _O (A)	V _F			I _R max (μA)	@V _R (V)	C _t typ. (pF)					
Standard	40	0.1	0.54	0.6	0.1	5	40	18	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.5	2.9 x 2.4
													
													
			0.56	0.62	0.1	5	40	15					
	30	0.2	0.45	0.58	0.1	2	25	-					TBAT54 
													TBAT54C 
													TBAT54S 
													TBAT54A 
		0.1	0.38	0.5	0.1	50	30	15					
	20	0.3	0.38	0.45	0.3	50	20	46					
10	0.1	0.35	0.5	0.1	20	10	20						
													
													

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						ESV (SOT-553)	US6 (SOT-363)	SM6 (SOT-26)
											
			V _R (V)	I _O (A)	V _F			I _R max (μA)	C _i typ. (pF)	1.6 x 1.6	2.0 x 2.1
			typ. (V)	max (V)	@I _F (A)		@V _R (V)				
Standard	40	0.1	0.54	0.6	0.1	5	40	18	HN2S02JE 	HN2S02FU 	
	20	0.2	0.36	0.42	0.2	50	20	46		HN2S04FU 	
	10	0.1	0.35	0.5	0.1	20	10	20		HN2S01FU 	HN2S01F 

AEC-Q101 qualified

Switching Diodes

Package Dimensions (unit: mm)

Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)		CST2 (SOD-882)	SOD-923	ESC (SOD-523)	USC (SOD-323)	CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	SOT23 (SOT-23)
VR (V)	Io (mA)	CI typ. (pF)	trr typ. (ns)	Bottom View								
												
80	80	0.5	1.6							1SS362 		
	100	0.3	1.6		1SS427							
		0.5	1.6	1SS387CT		1SS387 #	1SS352 #					
		0.9	1.6					1SS361CT 	1SS361FV # 	1SS361 # 	1SS301 # 	
									1SS362FV # 		1SS302A # 	
		2	-			1SS307E #						
		2.2	1.6							1SS360 # 	1SS300 # 	
	215	0.9	1.6									TBAS16 
												TBAW56 
100	150	0.9	4 (max)								BAV99W 	
	215	0.9	4 (max)									BAV70 
			3 (max)									BAV99 
	250	0.35	3 (max)			BAS516	BAS316					
		0.5	3 (max)			1N4148WT☆ #	1N4148WS☆					
200	100	1.5	10				1SS403 #				1SS370 	
			60 (max)			1SS403E						
400	100	2.5	0.5								1SS397 	

AEC-Q101 qualified

☆ New Products

Switching Diodes

Package Dimensions (unit: mm)

Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)		S-Mini (SOT-346)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)	ES6 (SOT-563)	US6 (SOT-363)	SM6 (SOT-26)
V _R (V)	I _O (mA)	C _T typ. (pF)	t _{rr} typ. (ns)							
30	100	3	-	1SS307 						
80	80	0.5	1.6						HN2D01FU # 	HN2D01F 
									HN2D02FU # 	
	100	0.5	1.6		HN2D01JE 					
				1SS184 # 		HN4D02JU 	1SS309 			
		0.9	1.6	1SS226 # 				HN1D02FE 	HN1D02FU # 	HN1D02F 
				1SS196 # 						
				1SS193 # 						
		2.2	1.6	1SS190 # 		HN4D01JU 	1SS308 			
				1SS187 # 				HN1D01FE 	HN1D01FU # 	HN1D01F 
				1SS181 # 						
		3	-	1SS379 # 						
									HN1D03FU # 	HN1D03F 
		Q1/2=0.9 Q3/4=2.2	1.6							
200	100	1.5	10	1SS250 						
400	100	2.5	0.5	1SS398 						HN2D03F 
		4.3	0.5					HN1D05FE ☆ 		

☆ New Products
AEC-Q101 qualified

① MOSFETs

② Tr./BRts

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

⑨ Packages

TVS Diodes (ESD Protection Diodes)

Package Dimensions (unit: mm)

Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			SL2 (SOD-962)	CST2 (SOD-882)	SOD-923	ESC (SOD-523)
							Bottom View	Bottom View		
										
							0.62 x 0.32	1.0 x 0.6	1.0 x 0.6	1.6 x 0.8
		V _{ESD} IEC61000 -4-2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{dyn} typ. (Ω)				
Bi-directional	USB3.1 / Thunderbolt™ / RF antenna	±20	2.5	3.3	0.3	0.5	DF2B5M5SL	DF2B5M5CT		
		±20	2.5	5	0.3	0.5	DF2B6M5SL	DF2B6M5CT		
		±20	2	3.6	0.2	0.5 to 0.8	DF2B5M4SL	DF2B5M4CT		
		±20	2	5.5	0.2	0.5 to 0.8	DF2B6M4SL	DF2B6M4CT		
		±16	2	3.6	0.15	0.7	DF2B5M4ASL			
		±15	2	5.5	0.15	0.7	DF2B6M4ASL			
		±15	1	11	0.2	0.65	DF2B12M4SL			
		±15	0.5	18.5	0.2	0.2	DF2B20M4SL			
		±15	0.5	24	0.2	0.2	DF2B26M4SL			
		±12	2.5	5.5	0.1	0.7	DF2B7M3SL			
		±12	2	5	0.2	1	DF2B7M2SL ●			
		±12	2.5	5	0.3	0.8		DF2B6.8M1ACT		
		±8	2	5.5	0.12	0.7	DF2B6M4BSL			
	USB2.0	±10	1.5	5.5	1.5	0.25	DF2B6USL			
	General Purpose / Audio / SIM Card	±30	27	5.5	45	0.1		DF2B7PCT		
		±30	4	5.5	8.5	0.2	DF2B7ASL	DF2B7ACT	DF2B7AFS	DF2B7AE
		±30	7.3	5.5	12	0.2	DF2B7BSL			
		±30	27	3.6	41	0.1		DF2B5PCT		
		±23	8	3.3	11	0.2	DF2B5BSL			
		±17	3	5.3	6	0.3	DF2B7SL			
		±17	5.5	3.3	7.2	0.25	DF2B5SL			
		±8	-	5	15	-				DF2B6.8E #
Uni-directional	USB3.1 / Thunderbolt™ / RF antenna (NFC)	±20	2	3.6	0.35 to 0.45	0.3 to 0.35	DF2S5M4SL	DF2S5M4CT	DF2S5M4FS ☆	
		±20	2	5.5	0.35 to 0.45	0.3 to 0.35	DF2S6M4SL	DF2S6M4CT	DF2S6M4FS ☆	
		±20	2.5	3.3	0.6	0.3	DF2S5M5SL	DF2S5M5CT		
		±20	2.5	5	0.6	0.3	DF2S6M5SL	DF2S6M5CT		
	USB2.0	±12	3	5	to 0.5	0.35	DF2S7MSL ●		DF2S6.8MFS	
	General Purpose / Audio / SIM Card	±30	2.5	1.5	45	0.2	DF2S5.1ASL			
		±30	2.5	3.5	40	0.25	DF2S5.6ASL			
		±30	2.5	5	32	0.3	DF2S6.2ASL			
		±30	2.5	5	25	0.5	DF2S6.8ASL			
		±30	2.5	6.5	20	0.8	DF2S8.2ASL			
		±30	2.5	8	16	0.5	DF2S10ASL ☆			
		±20	2.5	9	13	1.5	DF2S12ASL ☆			
		±12	2.5	12	10	0.6	DF2S16ASL			
		±12	2.5	15	9.5	1.25	DF2S20ASL ☆			
		±10	2.5	19	8.5	1.5	DF2S24ASL ☆			
		±8	2.5	23	7.5	4	DF2S30ASL ☆			

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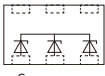
☆ New Products, # AEC-Q101 qualified

● Recommended Another New Product

DF2S7MSL → DF2S6M5SL, DF2B7M2SL → DF2B6M4SL

■ TVS Diodes (ESD Protection Diodes)

Package Dimensions (unit: mm)

Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			DFN5	DFN6	DFN10
							Bottom View	Bottom View	Bottom View
							 1.3 x 0.8	 1.25 x 1.0	 2.5 x 1.0
Bi-directional	USB3.1/ Thunderbolt™/ RF antenna	V _{ESD} IEC61000 -4-2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{DYN} typ. (Ω)	 G	 G	 G
		±20	2	3.6	0.2	0.5 to 0.8	DF5G5M4N	DF6D5M4N	DF10G5M4N
		±20	2	5.5	0.2	0.5 to 0.8	DF5G6M4N	DF6D6M4N	DF10G6M4N

Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			DFN5	DFN6	DFN10
							Bottom View	Bottom View	Bottom View
		V _{ESD} IEC61000 -4-2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{DYN} typ. (Ω)	 1.3 x 0.8	 1.25 x 1.0	 2.5 x 1.0
Bi-directional	USB3.1/ Thunderbolt™/ RF antenna	±12	2.5	5.5	0.2	1	DF5G7M2N		
		±8	-	5	0.3	0.9		DF6D7M1N	
		±8	-	5	0.3	0.9			DF10G7M1N

Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			USC (SOD-323)	SSM (SOT-416)	USM (SOT-323)	UDFN6B (SOT-1220)
							 2.5 x 1.25	 1.6 x 1.6	 2.0 x 2.1	 2.0 x 2.0
		V _{ESD} IEC61000 -4-2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{DYN} typ. (Ω)				
Bi-directional	General Purpose / Audio / SIM Card	±30	4	5.5	8.5	0.2	DF2B7AFU			
	Automotive's CAN/LIN	±30	2.5	12	9	0.8	DF2B18FU #		DF3D18FU #	
		±25	3	24	9	1.1	DF2B29FU #		DF3D29FU #	
		±20	2.5	28	6.5	1.5	DF2B36FU #		DF3D36FU #	
Uni-directional	USB2.0	±8	-	5	0.5	-		DF3D6.8MS		
	Power Supply USB_V _{BUS}	±30	80	5.5	600	0.08	DF2S6P2FU			
		±30	60	10	280	0.08	DF2S12P2FU			
		±30	50	12.6	270	0.08	DF2S14P2FU			
		±30	14	21	160	0.13	DF2S23P2FU			
		±30	110	22	-	0.01				DF6S25P3NU

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■ TVS Diodes (ESD Protection Diodes)

Package Dimensions (unit: mm)

Application	Absolute Maximum Ratings	Electrical Characteristics (Ta = 25 °C)			CST2 (SOD-882)	SOD-923	USC (SOD-323)
					Bottom View		
					1.0 x 0.6	1.0 x 0.6	2.5 x 1.25
	V _{ESD} IEC61000 -4-2 (kV)	V _Z min (V)	C _T typ. (pF)	Z _Z max (Ω)			
Uni-directional	±30	4.8	45	70		DF2S5.1FS	
	±30	5.3	40	30	DF2S5.6CT	DF2S5.6FS	
	±30	5.8	32	30	DF2S6.2CT	DF2S6.2FS	
	±30	6.4	25	30	DF2S6.8CT	DF2S6.8FS	
	±30	7.7	20	30	DF2S8.2CT	DF2S8.2FS	
	±30	9.4	16	30		DF2S10FS	
	±20	11.4	15	10 (typ.)			DF2S12FU
	±20	11.4	15	25		DF2S12FS	
	±12	15.3	10	35	DF2S16CT	DF2S16FS	
	±12	18.8	9	to 55	DF2S20CT	DF2S20FS	
General-Purpose / SIM Card / Power-Supply	±10	22.8	8.5	70		DF2S24FS	
	±8	28	7.2	75	DF2S30CT		
	±8	28	7	150		DF2S30FS	

Application	Absolute Maximum Ratings	Electrical Characteristics (Ta = 25 °C)			CST3 (SOT-883)	VESM (SOT-723)	USM (SOT-323)	S-Mini (SOT-346)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)	US6 (SOT-363)
					Bottom View							
					1.0 x 0.6	1.2 x 1.2	2.0 x 2.1	2.9 x 2.5	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	2.0 x 2.1
	V _{ESD} IEC61000 -4-2 (kV)	V _Z min (V)	C _T typ. (pF)	Z _Z max (Ω)								
Uni-directional	±30	5.3	65	40		DF3A5.6FV#	DF3A5.6FU	DF3A5.6F	DF5A5.6JE	DF5A5.6FU	DF5A5.6F	
	±30	5.8	55	30		DF3A6.2FV#	DF3A6.2FU	DF3A6.2F	DF5A6.2JE	DF5A6.2FU	DF5A6.2F	
	±30	6.4	45	25	DF3A6.8CT	DF3A6.8FV#	DF3A6.8FU	DF3A6.8F	DF5A6.8JE	DF5A6.8FU	DF5A6.8F	DF6A6.8FU
	±30	5.3	29	40					DF5A5.6CJE	DF5A5.6CFU		
	±30	5.8	25	30					DF5A6.2CJE	DF5A6.2CFU		
	±25	6.4	23	25					DF5A6.8CJE	DF5A6.8CFU		
	±8	5.3	8	50			DF3A5.6LFU		DF5A5.6LJE	DF5A5.6LFU		
	±8	5.3	8	3 (typ.)		DF3A5.6LFV#						
	±8	5.9	6.5	50		DF3A6.2LFV#	DF3A6.2LFU		DF5A6.2LJE	DF5A6.2LFU		
	±8	6.5	to 6	50	DF3A6.8LCT	DF3A6.8LFV#	DF3A6.8LFU		DF5A6.8LJE	DF5A6.8LFU	DF5A6.8LF	

AEC-Q101 qualified

Zener Diodes for Over Voltage Protection

Package Dimensions (unit: mm)

General type

Application	Electrical Characteristics (Ta = 25 °C)					ESC (SOD-523)	USC (SOD-323)	USM (SOT-323)	S-Mini (SOT-346)	SOT23 (SOT-23)
										
						1.6 x 0.8 Po = 150 mW*	2.5 x 1.25 Po = 200 mW*	2.0 x 2.1 Po = 150 mW*	2.9 x 2.5 Po = 200 mW*	2.9 x 2.4 Po = 320 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	max (μA)	V _R (V)					
Uni-directional General-Purpose/ SIM Card / Power-Supply	5.6	5.3 to 6	5	1	3.5	CEZ5V6	CUZ5V6	MUZ5V6	MSZ5V6	MKZ5V6
	6.2	5.8 to 6.6	5	2.5	5	CEZ6V2	CUZ6V2	MUZ6V2	MSZ6V2	MKZ6V2
	6.8	6.4 to 7.2	5	1.5	5.5	CEZ6V8	CUZ6V8	MUZ6V8	MSZ6V8	MKZ6V8
	7.5	7 to 7.9	5	0.1	6	CEZ7V5 ☆	CUZ7V5 ☆	MUZ7V5 ☆	MSZ7V5 ☆	MKZ7V5 ☆
	8.2	7.7 to 8.7	5	0.1	7	CEZ8V2	CUZ8V2	MUZ8V2	MSZ8V2	MKZ8V2
	9.1	8.5 to 9.6	5	0.1	7.5	CEZ9V1 ☆	CUZ9V1 ☆	MUZ9V1 ☆	MSZ9V1 ☆	MKZ9V1 ☆
	10	9.4 to 10.6	5	0.1	8	CEZ10V ☆	CUZ10V ☆	MUZ10V ☆	MSZ10V ☆	MKZ10V ☆
	11	10.4 to 11.6	5	0.1	9	CEZ11V ☆	CUZ11V ☆	MUZ11V ☆	MSZ11V ☆	MKZ11V ☆
	12	11.4 to 12.6	5	0.1	10	CEZ12V	CUZ12V	MUZ12V	MSZ12V	MKZ12V
	13	12.4 to 14.1	5	0.1	11	CEZ13V ☆	CUZ13V ☆	MUZ13V ☆	MSZ13V ☆	MKZ13V ☆
	15	13.8 to 15.6	5	0.1	12	CEZ15V ☆	CUZ15V ☆	MUZ15V ☆	MSZ15V ☆	MKZ15V ☆
	16	15.3 to 17.1	5	0.1	14	CEZ16V	CUZ16V	MUZ16V	MSZ16V	MKZ16V
	18	16.8 to 19.1	5	0.1	16	CEZ18V ☆	CUZ18V ☆	MUZ18V ☆	MSZ18V ☆	MKZ18V ☆
	20	18.8 to 21.2	5	0.1	17.6	CEZ20V	CUZ20V	MUZ20V	MSZ20V	MKZ20V
	22	20.8 to 23.3	5	0.1	18	CEZ22V ☆	CUZ22V ☆	MUZ22V ☆	MSZ22V ☆	MKZ22V ☆
	24	22.8 to 25.6	5	0.1	19	CEZ24V	CUZ24V	MUZ24V	MSZ24V	MKZ24V
	27	25.1 to 28.9	2	0.1	23	CEZ27V ☆	CUZ27V ☆	MUZ27V ☆	MSZ27V ☆	MKZ27V ☆
	30	28 to 32	2	0.1	27	CEZ30V	CUZ30V	MUZ30V	MSZ30V	MKZ30V
	33	31 to 35	2	0.1	30	CEZ33V ☆	CUZ33V ☆	MUZ33V ☆	MSZ33V ☆	MKZ33V ☆
	36	34 to 38	2	0.1	32.5	CEZ36V	CUZ36V	MUZ36V	MSZ36V	MKZ36V

General type (For Automotive)

Application	Electrical Characteristics (Ta = 25 °C)					USC
						
						2.5 x 1.25 Po = 200 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	max (μA)	V _R (V)	
Uni-directional General-Purpose/ SIM Card / Power-Supply	5.6	5.3 to 6	5	1	2.5	XCUZ5V6 ☆ #
	6.2	5.8 to 6.6	5	1	3	XCUZ6V2 ☆ #
	6.8	6.4 to 7.2	5	0.5	3.5	XCUZ6V8 ☆ #
	7.5	7 to 7.9	5	0.5	4	XCUZ7V5 ☆ #
	8.2	7.7 to 8.7	5	0.1	5	XCUZ8V2 ☆ #
	9.1	8.5 to 9.6	5	0.1	6	XCUZ9V1 ☆ #
	10	9.4 to 10.6	5	0.1	7	XCUZ10V ☆ #
	11	10.4 to 11.6	5	0.1	8	XCUZ11V ☆ #
	12	11.4 to 12.6	5	0.1	9	XCUZ12V ☆ #
	13	12.4 to 14.1	5	0.1	10	XCUZ13V ☆ #
	15	13.8 to 15.6	5	0.1	11	XCUZ15V ☆ #
	16	15.3 to 17.1	5	0.1	12	XCUZ16V ☆ #
	18	16.8 to 19.1	5	0.1	13	XCUZ18V ☆ #
	20	18.8 to 21.2	5	0.1	15	XCUZ20V ☆ #
	22	20.8 to 23.3	5	0.1	17	XCUZ22V ☆ #
	24	22.8 to 25.6	5	0.1	19	XCUZ24V ☆ #
	27	25.1 to 28.9	2	0.1	21	XCUZ27V ☆ #
	30	28 to 32	2	0.1	23	XCUZ30V ☆ #
	33	31 to 35	2	0.1	25	XCUZ33V ☆ #
	36	34 to 38	2	0.1	27	XCUZ36V ☆ #

☆ New Products

* Please refer to the data sheet for the conditions of the measurement board.

AEC-Q101 qualified

① MOSFETs

② Tr./BJTs

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

⑨ Packages

Power type

Application	Electrical Characteristics (Ta = 25 °C)					US2H (SOD-323HE)
						 2.5 x 1.4 Po = 500 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	I _R max (μA)	V _R (V)	
Uni-directional General-Purpose / SIM Card / Power-Supply	5.6	5.3 to 6	10	10	3.5	CUHZ5V6
	6.2	5.8 to 6.6	10	10	5	CUHZ6V2
	6.8	6.4 to 7.2	10	0.5	5.5	CUHZ6V8
	8.2	7.7 to 8.7	10	0.1	7	CUHZ8V2
	12	11.4 to 12.6	10	0.1	10	CUHZ12V
	16	15.3 to 17.1	10	0.1	14	CUHZ16V
	20	18.8 to 21.2	10	0.1	17.6	CUHZ20V
	24	22.8 to 25.6	10	0.1	19	CUHZ24V
	30	28 to 32	10	0.1	27	CUHZ30V
	36	34 to 38	9	0.1	32.5	CUHZ36V

Ultra Small type

Application	Electrical Characteristics (Ta = 25 °C)					SL2 (SOD-962)
						Bottom View  0.62 x 0.32 Po = 150 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	I _R max (μA)	V _R (V)	
Uni-directional General-Purpose / SIM Card / Power-Supply	5.6	5.3 to 6	5	1	3.5	CSLZ5V6 ☆
	6.2	5.8 to 6.6	5	2.5	5	CSLZ6V2 ☆
	6.8	6.4 to 7.2	5	0.5	5	CSLZ6V8 ☆
	8.2	7.7 to 8.7	5	0.5	6.5	CSLZ8V2 ☆
	10	9.4 to 10.6	5	0.5	8	CSLZ10V ☆
	12	11.4 to 12.6	5	0.5	9	CSLZ12V ☆
	16	15.3 to 17.1	5	0.5	12	CSLZ16V ☆
	20	18.8 to 21.2	5	0.5	15	CSLZ20V ☆
	24	22.8 to 25.6	5	0.5	19	CSLZ24V ☆
	30	28 to 31.5	2	0.5	23	CSLZ30V ☆

☆ New Products
 * Please refer to the data sheet for the conditions of the measurement board.

■ Part Naming Conventions

Diode (JEITA Registration Products)

1 S S 181

Serial number: JEITA registration number.

The kind of diode

S: Diode of general-purpose use, detection use, frequency conversion use, and switching use
V: Variable capacitance and PIN diode

S stands for Semiconductor

The value that subtracted 1 from the total number of terminals

Schottky Barrier Diodes

New Naming Conventions

CU S 05 F 30 A

Revision or function category (A to Z)

Voltage rating

Ex.) 30: 30 V

Device type

Ex.) S: Super Low forward voltage F: Low forward voltage, R: Low leakage current

Current rating

Ex.) 05: 0.5 A

Pin count

Ex.) S: 2pin

Package

Ex.) CU: USC, CE: ESC, CB: CST2B, CL: CL2E

Old Naming Conventions

DS F 07 S 30 A U

Package style: This letter shows the package style.

Revision

Voltage rating

Ex.) 30: 30 V, 15: 15 V

Circuit configuration and number of pins

Current rating

Ex.) 07: 0.7 A, 10: 1 A

Device feature: This letter shows the feature of a device.

F: Low forward voltage type.
R: Low leakage current type.

Schottky barrier diode.

TVS Diodes (ESD Protection Diodes)

DF 5 A 6.2 L FU

Package suffix

Series name

Ex.) L: Ultra-high-speed

Reverse Breakdown Voltage (V_{BR})

Internal configuration

Ex.) A: Common anode

Pin count

TVS Diodes (ESD Protection Diodes)

Zener Diodes for Over Voltage Protection

CU Z 6V8

Zener voltage

Ex.) 6V8: 6.8 V

The kind of diode

Z: Zener Diode (uni-directional type)

Package

CU: USC
CUH: US2H
CE: ESC

MS: S-Mini
MU: USM
MK: SOT23

CSL: SL2

Note: The name of AEC-Q100 qualified product is XCUZxxx.

4. Power Management ICs

■ Low Dropout Regulators (LDO)

Package Dimensions (unit: mm)

WCSP4E	WCSP4F	SDFN4E	DFN4D	DFN4E	DFN4F	DFN5B	ESV (SOT-553)	UFV (SOT-353F)	SMV (SOT-25)	WCSP6F
Bottom View	Bottom View	Bottom View	Bottom View	Bottom View	Bottom View	Bottom View				Bottom View
										
0.645 x 0.645	0.645 x 0.645	0.8 x 0.8	1.0 x 1.0	1.0 x 1.0	1.0 x 1.0	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	1.2 x 0.8

CMOS LDO Regulators

Series Name / Part Number	Package	V _{OUT} typ. (V)	V _{IN} (V)	I _{OUT} (mA)	I _B typ. (μA)	Function							
						Over current protection	Auto discharge	Fast load transient response circuit	Thermal shutdown	Inrush current protection	Under voltage lockout	High PSRR	Control pin connection
TCR1HFxxB ☆	SMV	1.8 to 5	V _{OUT} +1 to 36	150	1	✓	✓ (A version)	✓	✓	✓			Pull up
TCR2ENxxx	SDFN4E	1 to 3.6	1.5 to 5.5	200	35	✓	✓	✓					Pull down
TCR2LNxxx		0.8 to 3.6	1.5 to 5.5	200	1	✓	✓						Pull down
TCR2EExxx	ESV	1 to 5	1.5 to 5.5	200	35	✓	✓	✓					Pull down
TCR2LExxx		0.8 to 3.6	1.5 to 5.5	200	1	✓	✓						Pull down
TCR2EFxxx	SMV	1 to 5	1.5 to 5.5	200	35	✓	✓	✓					Pull down
TCR2LFxxx		0.8 to 3.6	1.5 to 5.5	200	1	✓	✓						Pull down
TCR3DGxxx	WCSP4E	1 to 4.5	1.75 to 5.5	300	65	✓	✓	✓	✓	✓			Pull down
TCR3LMxxA ☆	DFN4D	0.8 to 5	1.4 to 5.5	300	1.2	✓	✓		✓				Pull down
TCR3DMxxA ☆		1 to 4.5	1.5 to 5.5	300	86	✓	✓		✓	✓			Pull down
TCR3EMxxA ☆	SMV	0.8 to 5	1.3 to 5.5	300	35	✓	✓		✓				Pull down
TCR3DMxxx		1 to 4.5	1.75 to 5.5	300	65	✓	✓	✓	✓	✓			Pull down
TCR3DFxxx	SMV	1 to 4.5	1.8 to 5.5	300	65	✓	✓	✓	✓	✓			Pull down
TCR3UGxxxA	WCSP4F	0.8 to 5	1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓			Pull down
TCR3UGxxxB		1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓				Pull down
TCR3UMxxxA	DFN4E	0.8 to 5	1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓			Pull down
TCR3UFxxxA	SMV	0.8 to 5	1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓			Pull down
TCR3UFxxxB		1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓				Pull down
TCR3RMxxxA	DFN4F	0.9 to 4.5	1.8 to 5.5	300	7	✓	✓	✓	✓	✓		✓	Pull down
TCR4DGxxx	WCSP4E	1 to 4.5	V _{OUT} +V _{DO} to 5.5	420	65	✓	✓	✓	✓	✓			Pull down
TCR5RGxxxA	WCSP4F	0.9 to 5	1.8 to 5.5	500	7	✓	✓	✓	✓	✓		✓	Pull down
TCR5BMxxxA	DFN5B	0.8 to 3.6	V _{OUT} +V _{DO} to V _{BIAS}	500	19	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR8BMxxxA		0.8 to 3.6	V _{OUT} +V _{DO} to V _{BIAS}	800	20	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR13AGADJ	WCSP6F	0.55 to 3.6 adjustable	V _{OUT} +0.1V to V _{BIAS}	1300	56	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR15AGxxx	WCSP6F	0.65 to 3.6	V _{OUT} +V _{DO} to V _{BIAS}	1500	25	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR15AGADJ	WCSP6F	0.6 to 3.6 adjustable	V _{OUT} +V _{DO} to V _{BIAS}	1500	25	✓	✓	✓	✓	✓	✓	✓	Pull down

Bipolar LDO Regulators

Series Name	Package	V _{OUT} typ. (V)	V _{IN} (V)	I _{OUT} (mA)	I _B typ. (μA)	Function				
						Over current protection	Auto discharge	Fast load transient response circuit	Thermal shutdown	Control pin connection
TAR5SxxU	UFV	1.5 to 5	2.4 to 15	200	170	✓			✓	
TAR5Sxx	SMV	1.5 to 5	2.4 to 15	200	170	✓			✓	
TAR5SBxx						✓			✓	

☆ New Products

Load Switch ICs

Package Dimensions (unit: mm)

WCSP4D	WCSP4C	SMV (SOT-25)	WCSP6C	WCSP6E	DFN4A	WCSP4G
Bottom View	Bottom View		Bottom View	Bottom View	Bottom View	Bottom View
0.79 x 0.79	0.9 x 0.9	2.9 x 2.8	1.5 x 1.0	1.2 x 0.8	1.2 x 1.2	0.645 x 0.645

Part Number	Package	Operating voltage range (V)	Output current (A)	R _{DS(on)} (1) typ. (mΩ)	R _{DS(on)} (2) typ. (mΩ)	Function						Note	
						Inrush current reduction (Slew Rate control)	Thermal shutdown	Over current protection	Auto discharge	Under voltage lockout	Reverse current block		Control pin connection (Active Level)
TCK106AG	WCSP4D	1.1 to 5.5	1	176 @1.1 V, -0.2 A	34 @5 V, -0.5 A	✓						Pull down (H)	
TCK107AG					✓			✓			Pull down (H)		
TCK108AG					✓			✓			Open (L)		
TCK106AF	SMV		1	223 @1.1 V, -0.2 A	63 @5 V, -0.5 A	✓						Pull down (H)	
TCK107AF					✓			✓			Pull down (H)		
TCK108AF					✓			✓			Open (L)		
TCK111G ★	WCSP6C	1.1 to 5.5	3	8.5 @1.1 V, -1.5 A	8.3 @5 V, -1.5 A	✓	✓				True Reverse Current Blocking	Pull down (H)	
TCK112G ★					✓	✓		✓			Pull down (H)		
TCK126BG ☆	WCSP4G		1	343 @1 V, -0.05 A	46 @5 V, -0.5 A	✓						Open (H)	Ultra small Iq 0.08 nA
TCK127BG ☆					✓			✓			Open (H)		
TCK128BG ☆					✓			✓			Open (L)		
TCK22921G	WCSP6E	1.1 to 5.5	2	136 @1.1 V, -0.5 A	25 @5 V, -0.5 A	4.5 μs			✓		✓	Pull down (H)	
TCK22922G						666 μs			✓		✓	Pull down (H)	
TCK22923G						1364 μs			✓		✓	Pull down (H)	
TCK22925G						3380 μs			✓		✓	Pull down (H)	
TCK22971G						4.5 μs					✓	Pull down (H)	
TCK22972G						666 μs					✓	Pull down (H)	
TCK22973G						1364 μs					✓	Pull down (H)	
TCK22974G						3380 μs					✓	Pull down (H)	
TCK22975G						666 μs					✓	Open (L)	
TCK22910G	WCSP6E	1.1 to 5.5	2	179 @1.1 V, -0.15 A	31 @5 V, -0.15 A	1400 μs	✓			✓	True Reverse Current Blocking	Open (L)	
TCK22911G						1400 μs	✓		✓	✓		Open (L)	
TCK22912G						1400 μs	✓		✓	✓		Pull down (H)	
TCK22913G						1400 μs	✓		✓	✓		Pull down (H)	
TCK22946G	WCSP6E	1.1 to 5.5	0.4	179 @1.1 V, -0.15 A	31 @5 V, -0.15 A	50 μs	✓	400 mA	✓	✓	True Reverse Current Blocking	Pull down (H)	
TCK22951G			0.74			50 μs	✓	740 mA	✓	✓		Pull down (H)	
TCK2065G		1.4 to 5.5	1.11			50 μs	✓	1110 mA	✓	✓		Pull down (H)	
TCK1024G			1.54			50 μs	✓	1540 mA	✓	✓		Pull down (H)	
TCK22891G			0.4			50 μs	✓	400 mA	✓			Pull down (H)	
TCK22892G			0.74			50 μs	✓	740 mA	✓			Pull down (H)	
TCK22893G			1.11			50 μs	✓	1110 mA	✓			Pull down (H)	
TCK22894G			1.54			50 μs	✓	1540 mA	✓			Pull down (H)	
TCK206G	WCSP4C	0.75 to 3.6	2	18.4 @0.75 V, -1.5 A	18.1 @3.3 V, -1.5 A	✓					✓	Pull down (H)	
TCK207G					✓			✓		✓	Pull down (H)		
TCK208G					✓			✓		✓	Open (L)		
TCK207AN	DFN4A				21.5 @0.75 V, -1.5 A	21.5 @3.3 V, -1.5 A	✓			✓		✓	Pull down (H)

☆ New Products

★ Under Development (The specification is subject to change without notice.)

① MOSFETs

② Tr./BRTs

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

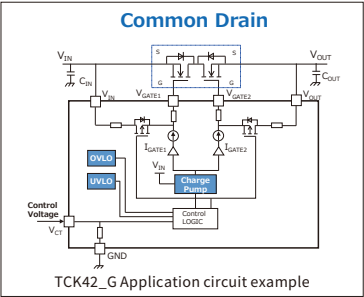
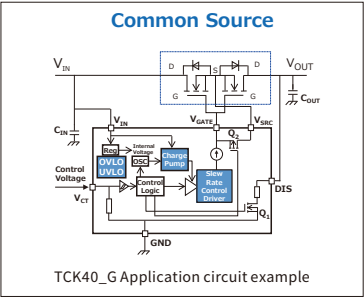
⑨ Packages

N-ch MOSFET Gate driver ICs with OVP function

Package Dimensions (unit: mm)

WCSP6E	WCSP6G
Bottom View	Bottom View
	
1.2 x 0.8	1.2 x 0.8

Part Number	Package	Operating voltage range (V)	Input quiescent current (ON state) @V _{IN} = 5 V	Gate drive voltage (1) @V _{IN} = 3 V	Gate drive voltage (2) @V _{IN} = 5 V	Function					Note	
						Inrush current reduction	Under voltage lockout	Over voltage lock out (Typ.)	Auto discharge	Reverse current block		Control pin connection (Active Level)
TCK401G	WCSP6E	2.7 to 28	121 μA typ. @V _{IN} = 5 V	4 V typ. @V _{IN} = 3 V	6.5 V typ. @V _{IN} = 5 V	✓	✓	✓ (28 V)	✓	Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Source MOSFET or Single High Side MOSFET
TCK402G											Pull down (L)	
TCK420G ☆	WCSP6G	2.7 to 28	220 μA typ. @V _{IN} = 20 V	9.2 V typ. @V _{IN} = 2.7 V	10 V typ. @V _{IN} = 24 V	✓	✓	✓ (27.73 V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 24 V
TCK421G ☆	WCSP6G	2.7 to 28	220 μA typ. @V _{IN} = 20 V	9.2 V typ. @V _{IN} = 2.7 V	10 V typ. @V _{IN} = 20 V	✓	✓	✓ (23.26 V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 20 V
TCK422G ☆	WCSP6G	2.7 to 28	185 μA typ. @V _{IN} = 12 V	9.2 V typ. @V _{IN} = 2.7 V	10 V typ. @V _{IN} = 12 V	✓	✓	✓ (14.29 V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 12 V
TCK423G ☆	WCSP6G	2.7 to 28	140 μA typ. @V _{IN} = 12 V	5.6 V typ. @V _{IN} = 2.7 V	5.6 V typ. @V _{IN} = 12 V	✓	✓	✓ (14.29 V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 12 V
TCK424G ☆	WCSP6G	2.7 to 28	125 μA typ. @V _{IN} = 9 V	5.6 V typ. @V _{IN} = 2.7 V	5.6 V typ. @V _{IN} = 9 V	✓	✓	✓ (10.83 V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 9 V
TCK425G ☆	WCSP6G	2.7 to 28	100 μA typ. @V _{IN} = 5 V	5.6 V typ. @V _{IN} = 2.7 V	5.6 V typ. @V _{IN} = 5 V	✓	✓	✓ (6.31 V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 5 V



☆ New Products

Power Multiplexer ICs

Package Dimensions (unit: mm)

WCSP9	WCSP16C
Bottom View	Bottom View
	
1.5 x 1.5	1.9 x 1.9

Part Number	Package	Operating voltage range (V)	Output current (A)	R _{DS(on)} typ. (mΩ) @Ta = 25 °C	R _{DS(on)} max (mΩ) @Ta = -40 to 85 °C	Function						Flag Operation Monitored input	Note
						Inrush current reduction	Thermal shutdown	Under voltage lockout	Over voltage lockout	Auto discharge	Reverse current block	Control pin connection (Active Level)	
TCK301G	WCSP9	2.3 to 28	3	73 @4.5 V, -1 A	140 @4.5 V, -1 A	✓	✓	✓	6.6 V		✓	Pull up (H)	-
TCK302G						✓	✓	✓	10.5 V		✓		-
TCK303G						✓	✓	✓	15.5 V		✓		-
TCK304G						✓	✓	✓	6.6 V		✓	Pull down (L)	-
TCK305G						✓	✓	✓	10.5 V		✓		-
TCK321G	WCSP16C	2.3 to 36	2	98 @4.5 V, -1 A	170 @4.5 V, -1 A	✓	✓	✓	V _{MAX} = V _{INB} = 12 V		✓	Pull down	V _{INA}
TCK322G						✓	✓	✓	V _{MAX} = V _{INB} = 15 V		✓		V _{INA}
TCK323G						✓	✓	✓	V _{MAX} = V _{INB} = 15 V		✓		V _{INB}

eFuse ICs

WSN10B	WSN10	WSN8
Bottom View	Bottom View	Bottom View
		
3.0 x 3.0	3.0 x 3.0	2.0 x 2.0

Part Number	Package	Operating voltage range (V)	Output current (A)	R _{DS(on)} typ. (mΩ) @T _a = 25 °C	R _{DS(on)} max (mΩ) @T _a = -40 to 85 °C	Function							Note	
						Inrush current reduction	Thermal shutdown	Over voltage Clamp	Auto discharge	Under voltage lockout	Reverse current blocking	Fault Response		Over current protection
TCKE712BNL ☆	WSN10	4.4 to 13.2	3.65	53 @12 V, -1 A	80 @12 V, -1 A	Slew rate control by External Capacitance	✓	Adjustable		✓		Latched	Adjustable	FLAG Indicates
TCKE805NA	WSN10B	4.4 to 18	5	28 @5 V, -1.5 A	38 @5 V, -1.5 A		✓	6.04 V typ.	✓	✓	*	Auto-retry	Adjustable	
TCKE805NL							✓	6.04 V typ.	✓	✓	*	Latched	Adjustable	
TCKE812NA							✓	15.1 V typ.	✓	✓	*	Auto-retry	Adjustable	
TCKE812NL							✓	15.1 V typ.	✓	✓	*	Latched	Adjustable	
TCKE800NA							✓	None	✓	✓	*	Auto-retry	Adjustable	
TCKE800NL							✓	None	✓	✓	*	Latched	Adjustable	
TCKE903NA ☆	WSN8	2.7 to 23	4	34 @5 V, -1.5 A	52 @5 V, -1.5 A T _a = -40 to 125 °C	Slew rate control by External Capacitance	✓	3.87 V typ.	✓	✓		Auto-retry	Adjustable	FLAG Indicates
TCKE903NL ☆							✓	3.87 V typ.	✓	✓		Latched	Adjustable	
TCKE905ANA ☆							✓	5.7 V typ.	✓	✓		Auto-retry	Adjustable	
TCKE905NL ☆							✓	5.7 V typ.	✓	✓		Latched	Adjustable	
TCKE912NA ☆							✓	13.7 V typ.	✓	✓		Auto-retry	Adjustable	
TCKE912NL ☆							✓	13.7 V typ.	✓	✓		Latched	Adjustable	
TCKE920NA ☆							✓	22.2 V typ.	✓	✓		Auto-retry	Adjustable	
TCKE920NL ☆							✓	22.2 V typ.	✓	✓		Latched	Adjustable	
TCKE903QNA ☆							✓	3.87 V typ. ✓ (Quick Discharge)	✓	✓		Auto-retry	Adjustable	
TCKE905QNA ☆							✓	5.7 V typ. ✓ (Quick Discharge)	✓	✓		Auto-retry	Adjustable	

☆ New Products

* This function is supported when N-ch MOSFET is attached to the external terminal.

① MOSFETs

② Tr./BJTs

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

⑨ Packages

5. Linear ICs

■ Thermoflagger™ (Over Temperature Detection IC)

Package Dimensions (unit: mm)



	TCTH011AE ☆ Push-pull	TCTH012AE ☆ Push-pull	TCTH021AE ☆ Push-pull	TCTH022AE ☆ Push-pull	TCTH011BE ☆ Open-drain	TCTH012BE ☆ Open-drain	TCTH021BE ☆ Open-drain	TCTH022BE ☆ Open-drain
Package	ESV	ESV	ESV	ESV	ESV	ESV	ESV	ESV
Supply Voltage	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V
Operation Temperature	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C
PTCO output current (typ.)	1 μA	1 μA	10 μA	10 μA	1 μA	1 μA	10 μA	10 μA
FLAG signal latch function	-	included	-	included	-	included	-	included
Current Consumption (max)	2.6 μA	2.6 μA	16.5 μA	16.5 μA	2.6 μA	2.6 μA	16.5 μA	16.5 μA
High level output voltage @I _{PTCGOOD} = -4 mA	3.03 V (min) @V _{DD} = 3.3 V	3.03 V (min) @V _{DD} = 3.3 V	3.03 V (min) @V _{DD} = 3.3 V	3.03 V (min) @V _{DD} = 3.3 V	-	-	-	-
Low level output voltage @I _{PTCGOOD} = 4 mA	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V

☆ New Products

“Thermoflagger™” is a trademark of Toshiba Electronic Devices & Storage Corporation.

Operational Amplifiers, Comparators

Package Dimensions (unit: mm)

MP6C	USV (SOT-353)	UFV (SOT-353F)	SMV (SOT-25)	US8 (SOT-765)	SM8 (SOT-505)
Bottom View					
1.45 x 1.0	2.0 x 2.1	2.0 x 2.1	2.9 x 2.8	2.0 x 3.1	2.9 x 4.0

Operational Amplifiers

	Type Package	Bipolar	
		Standard	Low Noise Wide Band
Single	SMV	TA75S01F	TA75S58F
Dual	SM8	TA75W01FU	TA75W58FU
V _{CC} , V _{EE} / V _{DD} , V _{SS}		±6 or 12 V	±18 V
Test condition		V _{CC} = 5 V V _{EE} = GND	V _{CC} = 15 V V _{EE} = -15 V
I _{CC} / I _{DD} (max)		0.8 mA @Single 1.2 mA @Dual	4 mA @Single 6 mA @Dual
V _{IO} (max)		7 mV	6 mV
I _{sink} (typ.)		20 mA	40 mA
I _{source} (typ.)		40 mA	40 mA
G _v (typ.)		100 dB	100 dB
V _{NI} (typ.)			2.5 μVrms
SR (typ.)			1 V / μs
f _r (typ.)		0.3 MHz	3 MHz

	Type Package	CMOS						
		Low Voltage Operation	Standard	Low I _{DD}	Low I _{DD} I/O Full range	Ultra Low I _{DD} I/O Full range	Low Noise	Ultra Low Noise
Single	USV	TC75S51FU	TC75S54FU	TC75S55FU			TC75S63TU	TC75S67TU
	UFV							
	SMV	TC75S51F	TC75S54F	TC75S55F	TC75S103F ☆	TC75S102F ☆		
Dual	US8	TC75W51FK	TC75W54FK	TC75W55FK				
	SM8	TC75W51FU	TC75W54FU	TC75W55FU				
V _{CC} , V _{EE} / V _{DD} , V _{SS}		7 V	7 V	7 V	6 V	6 V	6 V	6 V
Test condition		V _{DD} = 3 V	V _{DD} = 3 V	V _{DD} = 3 V	V _{DD} = 3.3 V	V _{DD} = 1.5 V	V _{DD} = 3.3 V	V _{DD} = 3.3 V
I _{CC} / I _{DD} (max)		200 μA @Single 400 μA @Dual	200 μA @Single 400 μA @Dual	20 μA @Single 40 μA @Dual	165 μA	0.46 μA	650 μA	700 μA
V _{IO} (max)		10 mV	10 mV	10 mV	1.85 mV	1.3 mV	7 mV	3 mV
I _{sink} (typ.)			700 μA	450 μA	10 mA	0.4 mA	1.5 mA (min)	3.5 mA
I _{source} (typ.)			200 μA	20 μA	10 mA	0.6 mA	1.5 mA (min)	2.5 mA
G _v (typ.)		70 dB	70 dB	70 dB	125 dB	139 dB	100 dB	100 dB
V _{NI} (typ.)							7.8 nV / √Hz	6 nV / √Hz
SR (typ.)		0.5 V / μs	0.7 V / μs	0.08 V / μs	0.4 V / μs	0.37 V / ms	1 V / μs	1 V / μs
f _r (typ.)		0.6 MHz	0.9 MHz	0.16 MHz	0.36 MHz	0.5 kHz	3.5 MHz	3.5 MHz

Comparators

	Type Package	Bipolar	CMOS				
		Standard	Push pull		Open drain		
			Full-range input/output	Low I _{DD}	High speed	Low I _{DD}	High speed
Single	MP6C		TC75S70L6X				
	USV			TC75S56FU	TC75S57FU	TC75S58FU	TC75S59FU
	SMV	TA75S393F		TC75S56F	TC75S57F	TC75S58F	TC75S59F
Dual	US8			TC75W56FK	TC75W57FK	TC75W58FK	TC75W59FK
	SM8	TA75W393FU		TC75W56FU	TC75W57FU	TC75W58FU	TC75W59FU
V _{CC} , V _{EE} / V _{DD} , V _{SS}		±18 or 36 V	±3 or 6 V	±3.5 or 7 V	±3.5 or 7 V	±3.5 or 7 V	±3.5 or 7 V
Test condition		V _{CC} = 5 V	V _{DD} = 3 V	V _{DD} = 5 V	V _{DD} = 5 V	V _{DD} = 5 V	V _{DD} = 5 V
I _{CC} / I _{DD} (max)		0.8 mA @Single 2 mA @Dual	35 μA	22 μA @Single 44 μA @Dual	220 μA @Single 440 μA @Dual	22 μA @Single 44 μA @Dual	220 μA @Single 440 μA @Dual
I _{sink} (typ.)		16 mA	18 mA	25 mA	25 mA	25 mA	25 mA
I _{source} (typ.)			15 mA	21 mA	21 mA		
G _v (typ.)		200 V / mV		94 dB	94 dB	94 dB	94 dB
t _{TRP} , t _{PLH} (typ.)		1.3 μs	400 ns	680 ns	140 ns	800 ns	200 ns

☆ New Products

① MOSFETs

② Tr./BRTs

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

⑨ Packages

6. Sensors

Magnetic Sensors

Package Dimensions (unit: mm)

UFV (SOT-353F)	SOT-23F
	
2.0 x 2.1	2.9 x 2.4

			TCS40DPR	TCS40DLR	TCS30DPU	TCS30DLU	TCS30SPU	TCS30NPU
			Push pull	Open drain	Push pull	Open drain	Push pull	
Package			SOT-23F		UFV			
Detective Polarity			S&N		S&N		S	N
Electrical Characteristics	Supply Voltage		2.3 to 5.5 V		2.3 to 3.6 V			
	Magnetic Flux Density	Operating Point (V _{CC} = 2.3 to 3.6 V)	B _{ON} = 3.4 mT (typ.)		B _{ON} = 1.8 mT (typ.)			
		Releasing Point (V _{CC} = 2.3 to 3.6 V)	B _{OFF} = 2 mT (typ.)		B _{OFF} = 0.8 mT (typ.)			
		Hysteresis (V _{CC} = 2.3 to 5 V)	B _H = 1.4 mT (typ.)		B _H = 1 mT (typ.)			
	Supply Current *	Average Current (V _{CC} = 2.3 V)	7.3 μA (typ.)		8.5 μA (typ.)			
	Operating Frequency (V _{CC} = 2.3 to 5 V)		25 Hz (typ.)		25 Hz (typ.)			

* Supply current is pulsed periodically by internal circuit.

7. General Purpose Logic ICs

7-1 One-Gate Logic ICs (L-MOS)

Package Dimensions (unit: mm)

VHS Series

General Specification	
Supply voltage range	: 2 to 5.5 V
Output current	: ± 8 mA (@ $V_{CC} = 4.5$ V)
Propagation delay time	: 3.7 nsec typ. (@ $V_{CC} = 5$ V)
Quiescent supply current	: 2 μ A max (@ $V_{CC} = 5.5$ V, $T_a = 25^\circ\text{C}$)
Operating temperature	: $T_{opr} = -40$ to 125°C

USV (SOT-353)	SMV (SOT-25)	US8 (SOT-765)	SM8 (SOT-505)
			
2.0 x 2.1	2.9 x 2.8	2.0 x 3.1	2.9 x 4.0

Function		Part Number					
		USV		SMV		US8	SM8
		-	TTL Input	-	TTL Input		
Gate / Buffer	NAND	TC7SH00FU #	TC7SET00FU #	TC7SH00F	TC7SET00F	TC7WH00FK # Dual-gate	TC7WH00FU Dual-gate
	AND	TC7SH08FU #	TC7SET08FU #	TC7SH08F	TC7SET08F	TC7WH08FK # Dual-gate	TC7WH08FU Dual-gate
		Open-drain TC7SH09FU #		TC7SH09F			
	NOR	TC7SH02FU #	TC7SET02FU #	TC7SH02F	TC7SET02F	TC7WH02FK # Dual-gate	TC7WH02FU Dual-gate
	OR	TC7SH32FU #	TC7SET32FU #	TC7SH32F	TC7SET32F	TC7WH32FK # Dual-gate	TC7WH32FU Dual-gate
	Exclusive-OR	TC7SH86FU #		TC7SH86F			
	Inverter	TC7SH04FU #	TC7SET04FU #	TC7SH04F	TC7SET04F	TC7WH04FK # Triple-gate	TC7WH04FU Triple-gate
		Unbuffered TC7SHU04FU #		TC7SHU04F		TC7WHU04FK # Triple-gate	TC7WHU04FU Triple-gate
		Schmitt TC7SH14FU #	TC7SET14FU #	TC7SH14F	TC7SET14F	TC7WH14FK # Triple-gate	TC7WH14FU Triple-gate
	Buffer	Schmitt TC7SH17FU #	TC7SET17FU #	TC7SH17F	TC7SET17F	TC7WH17FK # Triple-gate	TC7WH17FU Triple-gate
	Non-Inverter	TC7SH34FU #	TC7SET34FU #	TC7SH34F	TC7SET34F	TC7WH34FK # Triple-gate	TC7WH34FU Triple-gate
		3-state	Buffer	TC7SH125FU #	TC7SET125FU #	TC7WH125FK # Dual-gate	TC7WH125FU Dual-gate
				TC7SH126FU #	TC7SET126FU #	TC7WH126FK # Dual-gate	TC7WH126FU Dual-gate
D-Type Flip-Flop	Preset and Clear					TC7WH74FK #	TC7WH74FU
Multiplexers	Digital					TC7WH157FK #	TC7WH157FU

This device is compliant with the reliability requirements of AEC-Q100

SHS Series

General Specification	
Supply voltage range	: 1.65 to 5.5 V
Output current	: ± 24 mA (@ $V_{CC}=3$ V)
Propagation delay time	: 2.4 nsec typ. (@ $V_{CC}=3.3$ V)
Quiescent supply current	: 1 μ A max (@ $V_{CC}=5.5$ V, $T_a=25$ °C)
Operating temperature	: $T_{opr}=-40$ to 125 °C

fsv (SOT-953)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)	US6 (SOT-363)	US8 (SOT-765)	SM8 (SOT-505)
						
1.0 x 1.0	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	2.0 x 2.1	2.0 x 3.1	2.9 x 4.0

Function			Part Number						
	Package	fsv	ESV	USV	SMV	US6	US8	SM8	
Gate / Buffer	NAND	TC7SZ00AFS	TC7SZ00FE	TC7SZ00FU #	TC7SZ00F		TC7WZ00FK # Dual-gate	TC7WZ00FU Dual-gate	
	AND	TC7SZ08AFS	TC7SZ08FE	TC7SZ08FU #	TC7SZ08F		TC7WZ08FK # Dual-gate	TC7WZ08FU Dual-gate	
	NOR	TC7SZ02AFS	TC7SZ02FE	TC7SZ02FU #	TC7SZ02F		TC7WZ02FK # Dual-gate	TC7WZ02FU Dual-gate	
	OR	TC7SZ32AFS	TC7SZ32FE	TC7SZ32FU #	TC7SZ32F		TC7WZ32FK # Dual-gate	TC7WZ32FU Dual-gate	
	Exclusive-OR	TC7SZ86AFS	TC7SZ86FE	TC7SZ86FU #	TC7SZ86F		TC7WZ86FK # Dual-gate	TC7WZ86FU Dual-gate	
	Inverter		TC7SZ04AFS	TC7SZ04FE	TC7SZ04FU #	TC7SZ04F	TC7PZ04FU # Dual-gate	TC7WZ04FK # Triple-gate	TC7WZ04FU Triple-gate
		Unbuffered	TC7SZU04AFS	TC7SZU04FE	TC7SZU04FU #	TC7SZU04F		TC7WZU04FK # Triple-gate	TC7WZU04FU Triple-gate
		Open-drain	TC7SZ05AFS	TC7SZ05FE	TC7SZ05FU #	TC7SZ05F	TC7PZ05FU # Dual-gate	TC7WZ05FK # Triple-gate	TC7WZ05FU Triple-gate
		Schmitt	TC7SZ14AFS	TC7SZ14FE	TC7SZ14FU #	TC7SZ14F	TC7PZ14FU # Dual-gate	TC7WZ14FK # Triple-gate	TC7WZ14FU Triple-gate
	Buffer	Open-drain	TC7SZ07AFS	TC7SZ07FE	TC7SZ07FU #	TC7SZ07F	TC7PZ07FU # Dual-gate	TC7WZ07FK # Triple-gate	TC7WZ07FU Triple-gate
		Schmitt	TC7SZ17AFS	TC7SZ17FE	TC7SZ17FU #	TC7SZ17F	TC7PZ17FU # Dual-gate	TC7WZ17FK # Triple-gate	TC7WZ17FU Triple-gate
	Non-Inverter		TC7SZ34AFS	TC7SZ34FE	TC7SZ34FU #	TC7SZ34F	TC7PZ34FU # Dual-gate	TC7WZ34FK # Triple-gate	TC7WZ34FU Triple-gate
	3-state	Buffer	TC7SZ125AFS	TC7SZ125FE	TC7SZ125FU #	TC7SZ125F		TC7WZ125FK # Dual-gate	TC7WZ125FU Dual-gate
			TC7SZ126AFS	TC7SZ126FE	TC7SZ126FU #	TC7SZ126F		TC7WZ126FK # Dual-gate	TC7WZ126FU Dual-gate
D-Type Flip-Flop	Preset and Clear						TC7WZ74FK #	TC7WZ74FU	

This device is compliant with the reliability requirements of AEC-Q100

7UL1Gxx Series

General Specification	
Supply voltage range	: 0.9 to 3.6 V
Output current	: ± 8 mA (@V _{CC} = 3 V)
Propagation delay time	: 2.5 nsec typ. (@V _{CC} = 3.3 V)
Quiescent supply current	: 1 μ A max. (@V _{CC} = 3.6 V, T _a = 25 °C)
Operating temperature	: T _{opr} = -40 to 125 °C

fsv (SOT-953)	USV (SOT-353)	US8 (SOT-765)	XSON6 (MP6D)
			Bottom View 
1.0 x 1.0	2.0 x 2.1	2.0 x 3.1	1.45 x 1.0

Function		Part Number			
	Package	fsv	USV	US8	XSON6 (MP6D)
Gate / Buffer	NAND Gate	7UL1G00FS	7UL1G00FU	7UL2G00FK	7UL1G00NX ☆
	NOR Gate	7UL1G02FS	7UL1G02FU	7UL2G02FK	7UL1G02NX ★
	Inverter	7UL1G04FS	7UL1G04FU	7UL3G04FK	7UL1G04NX ☆
	Unbuffered	7UL1GU04FS	7UL1GU04FU	7UL3GU04FK	7UL1GU04NX ☆
	AND Gate	7UL1G08FS	7UL1G08FU	7UL2G08FK	7UL1G08NX ☆
	Schmitt Inverter	7UL1G14FS	7UL1G14FU	7UL3G14FK	7UL1G14NX ☆
	Schmitt Buffer	7UL1G17FS	7UL1G17FU	7UL3G17FK	7UL1G17NX ☆
	OR Gate	7UL1G32FS	7UL1G32FU	7UL2G32FK	7UL1G32NX ☆
	Buffer	7UL1G34FS	7UL1G34FU	7UL3G34FK	7UL1G34NX ☆
	Open drain		7UL1G07FU		
	Exclusive-OR	7UL1G86FS	7UL1G86FU	7UL2G86FK	7UL1G86NX ★
	3-State Buffer(/G)	7UL1G125FS	7UL1G125FU	7UL2G125FK	7UL1G125NX ☆
	3-State Buffer(G)	7UL1G126FS	7UL1G126FU	7UL2G126FK	7UL1G126NX ☆

7UL1Txx Series

General Specification	
Supply voltage range	: 2.3 to 3.6 V
Output level up to supply V _{CC} CMOS level	: 1.65 to 3.6 V (@V _{CC} = 3.6 V)
Output level down to supply V _{CC} CMOS level	: 3.6 to 2.3 V (@V _{CC} = 2.3 V)
Quiescent supply current	: 1 μ A max. (@V _{CC} = 3.6 V, T _a = 25 °C)
Operating temperature	: T _{opr} = -40 to 125 °C

fsv (SOT-953)	USV (SOT-353)	US8 (SOT-765)	XSON6 (MP6D)
			Bottom View 
1.0 x 1.0	2.0 x 2.1	2.0 x 3.1	1.45 x 1.0

Function		Part Number			
	Package	fsv	USV	US8	XSON6(MP6D)
Gate / Buffer	NAND Gate	7UL1T00FS	7UL1T00FU	7UL2T00FK	7UL1T00NX ★
	NOR Gate	7UL1T02FS	7UL1T02FU	7UL2T02FK	7UL1T02NX ★
	Inverter	7UL1T04FS	7UL1T04FU	7UL3T04FK	7UL1T04NX ★
	AND Gate	7UL1T08FS	7UL1T08FU	7UL2T08FK	7UL1T08NX ★
	OR Gate	7UL1T32FS	7UL1T32FU	7UL2T32FK	7UL1T32NX ★
	Buffer	7UL1T34FS	7UL1T34FU	7UL3T34FK	7UL1T34NX ★
	Exclusive-OR	7UL1T86FS	7UL1T86FU	7UL2T86FK	7UL1T86NX ★
	3-State Buffer(/G)	7UL1T125FS	7UL1T125FU	7UL2T125FK	7UL1T125NX ★
	3-State Buffer(G)	7UL1T126FS	7UL1T126FU	7UL2T126FK	7UL1T126NX ★

☆ New Products

★ Under Development (The specification is subject to change without notice.)

7-2 CMOS Logic ICs

■ Standard Logic 74VHC Series (TSSOP14B / 16B / 20B Package Products)

Package Dimensions (unit: mm)

TSSOP14B			TSSOP16B			TSSOP20B			Features		
									• Available -40 to 125 °C products • Compatible standard TSSOP package		
5.0 x 6.4			5.0 x 6.4			6.5 x 6.4					

Series name				VHC	VHCT (TTL Input)	VHCV (Schmitt Input)	VHC9 (Schmitt Input)		
Characteristics and Features		Supply voltage range		2 to 5.5 V	4.5 to 5.5 V	1.8 to 5.5 V	2 to 5.5 V 4.5 to 5.5 V (VHCT9)		
		Output current @V _{CC} = 4.5 V		±8 mA		±16 mA	±8 mA		
		Power down protection on inputs		Yes					
		Power down protection on outputs		No		Yes			
Function				Pin	-	-	-		
Gate / Buffer	NAND	Quad		14	74VHC00FT	74VHCT00AFT			
		Open-drain		14	74VHC03FT				
		Schmitt		14	74VHC132FT				
		Dual	4-input	14	74VHC20FT				
	AND	Quad		14	74VHC08FT	74VHCT08AFT			
		Dual	4-input	14	74VHC21FT				
	NOR	Quad		14	74VHC02FT				
		Dual	4-input	14	74VHC27FT				
	OR	Quad		14	74VHC32FT	74VHCT32AFT			
	Exclusive-OR Inverter	Quad		14	74VHC86FT				
		Hex		14	74VHC04FT	74VHCT04AFT			
		Open-drain		14	74VHC05FT		74VHCV05FT		
		Schmitt		14	74VHC14FT	74VHCT14AFT	74VHCV14FT		
	Buffer	9-bit		20				74VHC9152FT	
		Hex		14			74VHCV17FT		
		Open-drain		14			74VHCV07FT		
		Dual 3-bit	Pull-down resistor	20				74VHC9363FT	
		Pull-up resistor	20					74VHC9364FT	
		9-bit		20				74VHC9151FT	
	3-state Buffer	Quad		14	74VHC125FT	74VHCT125AFT			
				14	74VHC126FT	74VHCT126AFT			
		5-Bit Universal Schmitt Buffer		14				74VHC9125FT 74VHCT9125AFT 74VHC9126FT 74VHCT9126AFT	
				14					
		Octal	Inverted	20	74VHC240FT	74VHCT240AFT	74VHCV240FT		
				20	74VHC540FT	74VHCT540AFT	74VHCV540FT		
				20	74VHC244FT	74VHCT244AFT	74VHCV244FT		
				20	74VHC541FT	74VHCT541AFT	74VHCV541FT		
		Universal Schmitt Buffer	20				74VHC9541FT 74VHCT9541AFT		
	Flip-Flop	Transceiver	Octal		20	74VHC245FT	74VHCT245AFT	74VHCV245FT	
			Dual		14	74VHC74FT			
			Hex		16	74VHC174FT			
			Octal		20	74VHC273FT			74VHC9273FT 74VHCT9273FT
3-state		Octal		20	74VHC374FT		74VHCV374FT		
Latch	3-state	Octal		20	74VHC574FT	74VHCT574AFT	74VHCV574FT		
				20	74VHC373FT		74VHCV373FT		
				20	74VHC573FT	74VHCT573AFT	74VHCV573FT		
Multi-vibrator Decoder	Dual		16	74VHC123AFT					
			16	74VHC221AFT					
		3 to 8 line	Single	16	74VHC138FT	74VHCT138AFT			
Shift Register	8bit		16	74VHC238FT					
		2 to 4 line	Dual	16	74VHC139FT				
		S-in / P-out	14	74VHC164FT					
Counter	Binary	S-in / P-out, P-in / S-out	16				74VHC9164FT		
		P-in / S-out	16	74VHC165FT					
		3-state	16	74VHC595FT			74VHC9595FT		
		Single 4bit with Async. Clear	16	74VHC161FT					
		Sync. Clear	16	74VHC163FT					
		Dual 4bit	14	74VHC393FT					
Multi-plexer	Digital	Single	16	74VHC4020FT					
		14-stage	16	74VHC4040FT					
		12-stage	16	74VHC4040FT					
		Dual-4ch.	16	74VHC153FT					
		Quad-2ch.	16	74VHC157FT					
		Single-8ch.	16	74VHC4051AFT					
Other	Analog switch	Dual-4ch.	16	74VHC4052AFT					
		Triple-2ch.	16	74VHC4053AFT					
		Quad	14	74VHC4066AFT					

Standard Logic TC74VHC Series (TSSOP14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

TSSOP14	TSSOP16	TSSOP20
		
5.0 x 6.4	5.0 x 6.4	6.5 x 6.4

Features

- Compliant with the reliability requirements of AEC-Q100 Operating temperature: Available -40 to 125 °C products
- Compatible standard TSSOP package

Series name				VHC		VHCT (TTL Input)		VHCV (Schmitt Input)		VHC9 (Schmitt Input)	
Characteristics and Features				Supply voltage range		2 to 5.5 V		4.5 to 5.5 V		1.8 to 5.5 V	
				Output current @V _{cc} = 4.5 V		±8 mA				±16 mA	
				Power down protection on inputs		Yes					
				Power down protection on outputs		No		Yes			
Function				Pin		-		-		-	
Gate / Buffer	NAND	Quad		14	TC74VHC00FT #	TC74VHCT00AFT #					
			Open-drain Schmitt	14	TC74VHC03FT #						
		Dual	4-input	14	TC74VHC132FT #						
				14	TC74VHC20FT #						
	AND	Quad		14	TC74VHC08FT #	TC74VHCT08AFT #					
		Dual	4-input	14	TC74VHC21FT #						
	NOR	Quad		14	TC74VHC02FT #						
		Dual	4-input	14	TC74VHC27FT #						
	OR	Quad		14	TC74VHC32FT #	TC74VHCT32AFT #					
		Quad		14	TC74VHC86FT #						
	Exclusive-OR Inverter	Hex		14	TC74VHC04FT #	TC74VHCT04AFT #					
			Open-drain Schmitt	14	TC74VHC05FT #	TC74VHCT14AFT #		TC74VHCV14FT #			
		9-bit		20							TC74VHC9152FT #
		Buffer	Hex		14				TC74VHCV17FT #		
	Open-drain Pull-down resistor			14				TC74VHCV07FT #			
	Dual 3-bit		Pull-up resistor	20							TC74VHC9363FT #
				20							TC74VHC9364FT #
	9-bit			20							TC74VHC9151FT #
	3-state Buffer		Quad		14	TC74VHC125FT #	TC74VHCT125AFT #				
				14	TC74VHC126FT #	TC74VHCT126AFT #					
		5-Bit Universal Schmitt Buffer		14							TC74VHC9125FT #
											TC74VHCT9125AFT #
				14							TC74VHC9126FT #
											TC74VHCT9126AFT #
	Octal	Inverted		20	TC74VHC240FT #	TC74VHCT240AFT #		TC74VHCV240FT #			
				20	TC74VHC540FT #	TC74VHCT540AFT #		TC74VHCV540FT #			
				20	TC74VHC244FT #	TC74VHCT244AFT #		TC74VHCV244FT #			
				20	TC74VHC541FT #	TC74VHCT541AFT #		TC74VHCV541FT #			
		Universal Schmitt Buffer		20							TC74VHC9541FT #
											TC74VHCT9541AFT #
	Transceiver	Octal		20	TC74VHC245FT #	TC74VHCT245AFT #		TC74VHCV245FT #			
			14	TC74VHC74FT #							
Hex			16	TC74VHC174FT #							
			20	TC74VHC273FT #						TC74VHC9273FT #	
Octal			20	TC74VHC273FT #						TC74VHCT9273FT #	
3-state	Octal		20	TC74VHC374FT #			TC74VHCV374FT #				
			20	TC74VHC574FT #	TC74VHCT574AFT #		TC74VHCV574FT #				
Latch	3-state	Octal		20	TC74VHC373FT #			TC74VHCV373FT #			
				20	TC74VHC573FT #	TC74VHCT573AFT #		TC74VHCV573FT #			
Multi-vibrator		Dual		16	TC74VHC123AFT #						
				16	TC74VHC221AFT #						
Decoder	3 to 8 line	Single		16	TC74VHC138FT #	TC74VHCT138AFT #					
				16	TC74VHC238FT #						
	2 to 4 line	Dual		16	TC74VHC139FT #						
				16	TC74VHC164FT #						
Shift Register	8bit	S-in / P-out		14							
			S-in / P-out, P-in / S-out	16						TC74VHC9164FT #	
		P-in / S-out		16	TC74VHC165FT #						
				16	TC74VHC595FT #						
		3-state		16	TC74VHC161FT #						
				16	TC74VHC163FT #						TC74VHC9595FT #
Counter	Binary	Single 4bit with	Async. Clear	16	TC74VHC161FT #						
			Sync. Clear	16	TC74VHC163FT #						
		Dual	4bit	14	TC74VHC393FT #						
				16	TC74VHC4020FT #						
		Single	14-stage	16	TC74VHC4020FT #						
			12-stage	16	TC74VHC4040FT #						
Multi-plexer	Digital	Dual-4ch.		16	TC74VHC153FT #						
				16	TC74VHC157FT #						
	Analog	Single-8ch.		16	TC74VHC4051AFT #						
				16	TC74VHC4052AFT #						
		Dual-4ch.		16	TC74VHC4052AFT #						
			Triple-2ch.	16	TC74VHC4053AFT #						
Other	Analog switch	Quad		14	TC74VHC4066AFT #						

This device is compliant with the reliability requirements of AEC-Q100

1 MOSFETS

2 Tr./BJT's

3 Diodes

4 Power Management ICs

5 Linear ICs

6 Sensors

7 General Purpose Logic ICs

8 RF Devices

9 Packages

■ Standard Logic 74HC Series, 74LCX Series (TSSOP14B / 16B / 20B Package Products)

Package Dimensions (unit: mm)

TSSOP14B	TSSOP16B	TSSOP20B	Features
			74LCX Series • Available -40 to 125 °C products (‡ Operation temperature of this device is -40 to 85 °C.) • Compatible standard TSSOP package 74HC/HCT Series • Available -40 to 125 °C products, Compatible standard TSSOP package
5.0 x 6.4	5.0 x 6.4	6.5 x 6.4	

Series name				HC	HCT (TTL input)	LCX
Characteristics and Features				Supply voltage range		2 to 6 V
				Output current @V _{CC} = 4.5 V		4.5 to 5.5 V
				Power down protection on inputs		1.65 to 3.6 V to 5.5 V (05 and 07)
				Power down protection on outputs		±24 mA (@V _{CC} = 3 V)
						No
						Yes
						No
						Yes
						-
Gate / Buffer	NAND	Quad	14			74LCX00FT
						74LCX08FT
	AND	Quad	14			74LCX02FT
						74LCX32FT
	NOR	Quad	14			74LCX86FT
						74LCX04FT
	OR	Quad	14			TC74HC4049AFT &
						TC74HCU04AFT &
	Exclusive-OR	Quad	14			74LCX05FT
						74LCX14FT
	Inverter	Hex	14			TC74HC4050AFT &
						74LCX07FT
		Unbuffer	14			74LCX125FT
						74LCX126FT
		Open-drain	14			74LCX240FT ‡
						74LCX540FT ‡
		Schmitt	14			74LCX244FT ‡
						74LCX541FT ‡
	Buffer	Hex	16			74LCX245FT ‡
						74LCX74FT
		Open-drain	14			74LCX273FT
						74LCX374FT ‡
	3-state Buffer	Quad	14			74LCX574FT ‡
						74LCX257FT ‡
		Octal	20			74HC4538FT
						74LCX138FT
		Inverted	20			74LCX157FT
						74LCX257FT
			20			74HC4051FT
						74HC4052FT
			20			74HC4053FT
						74HCT4053FT
Transceiver	Octal		20			74HC4066FT
			14			
Flip-Flop		Dual	14			
	3-state	Octal	20			
Latch	3-state	Octal	20			
			20			
Multivibrator		Dual	Retriggerable / Resettable	16	74HC4538FT	
Decoder	3 to 8 line	Single		16		74LCX138FT
Multi-plexer	Digital	Quad-2ch.		16		74LCX157FT
	Analog	Single-8ch.		16	74HCT4051FT	74HCT4052FT
Other	Analog switch Quad			16	74HC4053FT	74HCT4053FT

‡ Operation temperature is -40 to 85 °C
& The package for this product is TSSOP14 / 16.

Standard Logic TC74LCX Series (TSSOP14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

TSSOP14	TSSOP16	TSSOP20	Features
			- Compliant with the reliability requirements of AEC-Q100 Operating temperature: Available -40 to 125 °C products (‡ Operation temperature of this device is -40 to 85 °C.) - Compatible standard TSSOP package
5.0 x 6.4	5.0 x 6.4	6.5 x 6.4	

Series name				LCX	
Characteristics and Features				Supply voltage range	1.65 to 3.6 V to 5.5 V (05 and 07)
				Output current @V _{CC} = 4.5 V	±24 mA (@V _{CC} = 3 V)
				Power down protection on inputs	Yes
				Power down protection on outputs	Yes
Function			Pin		
Gate / Buffer	NAND	Quad	14	TC74LCX00FT #	
	AND	Quad	14	TC74LCX08FT #	
	NOR	Quad	14	TC74LCX02FT #	
	OR	Quad	14	TC74LCX32FT #	
	Exclusive-OR	Quad	14	TC74LCX86FT #	
	Inverter	Hex	14	TC74LCX04FT #	
			Open-drain	14	TC74LCX05FT #
			Schmitt	14	TC74LCX14FT #
	Buffer	Hex	Open-drain	14	TC74LCX07FT #
	3-state Buffer	Quad	14	TC74LCX125FT #	
			14	TC74LCX126FT #	
		Octal	Inverted	20	TC74LCX240FT # ‡
				20	TC74LCX540FT # ‡
				20	TC74LCX244FT # ‡
				20	TC74LCX541FT # ‡
	Transceiver	Octal	20	TC74LCX245FT # ‡	
Flip-Flop		Dual	14	TC74LCX74FT #	
		Octal	20	TC74LCX273FT #	
	3-state	Octal	20	TC74LCX374FT # ‡	
			20	TC74LCX574FT # ‡	
Latch	3-state	Octal	20	TC74LCX373FT # ‡	
			20	TC74LCX573FT # ‡	
Decoder	3 to 8 line	Single	16	TC74LCX138FT #	
Multi-plexer	Digital	Quad-2ch.	16	TC74LCX157FT #	
		3-state	16	TC74LCX257FT #	

This device is compliant with the reliability requirements of AEC-Q100

‡ Operation temperature is -40 to 85 °C

■ Standard Logic 74VHC Series (US14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

US14	US16	US20	Features
			• Small mounting area and thin package
4.0 x 4.0	4.0 x 4.0	5.0 x 4.0	

Series name				VHC	VHCT (TTL Input)	VHCV (Schmitt Input)	VHC9 (Schmitt Input)		
Characteristics and Features		Supply voltage range		2 to 5.5 V	4.5 to 5.5 V	1.8 to 5.5 V	2 to 5.5 V 4.5 to 5.5 V (VHCT9)		
		Output current @V _{CC} = 4.5 V		±8 mA		±16 mA	±8 mA		
		Power down protection on inputs		Yes					
		Power down protection on outputs		No	Yes				
Function				Pin	-	-	-		
Gate / Buffer	NAND	Quad		14	TC74VHC00FK	TC74VHCT00AFK			
			Open-drain	14	TC74VHC03FK				
		Dual	Schmitt	14	TC74VHC132FK				
			4-input	14	TC74VHC20FK				
	AND	Quad		14	TC74VHC08FK	TC74VHCT08AFK			
		Dual	4-input	14	TC74VHC21FK				
	NOR	Quad		14	TC74VHC02FK				
		Dual	4-input	14	TC74VHC27FK				
	OR	Quad		14	TC74VHC32FK	TC74VHCT32AFK			
		Exclusive-OR	Quad		14		TC74VHC86FK		
	Inverter	Hex			14	TC74VHC04FK	TC74VHCT04AFK		
			Open-drain	14	TC74VHC05FK	TC74VHCV05FK			
		Schmitt		14	TC74VHC14FK	TC74VHCT14AFK	TC74VHCV14FK		
				20				TC74VHC9152FK	
	Buffer	Hex			14		TC74VHCV17FK		
			Open-drain	14			TC74VHCV07FK		
		9-bit		20				TC74VHC9151FK	
	3-state Buffer	Quad		14	TC74VHC125FK	TC74VHCT125AFK			
				14	TC74VHC126FK		TC74VHCT126AFK		
		5-Bit Universal Schmitt Buffer		14				TC74VHC9125FK TC74VHCT9125AFK TC74VHC9126FK TC74VHCT9126AFK	
				14					
			Octal	Inverted	20	TC74VHC240FK	TC74VHCT240AFK	TC74VHCV240FK	
					20	TC74VHC540FK	TC74VHCT540AFK	TC74VHCV540FK	
	20	TC74VHC244FK			TC74VHCT244AFK	TC74VHCV244FK			
	20	TC74VHC541FK			TC74VHCT541AFK	TC74VHCV541FK			
		Universal Schmitt Buffer	20				TC74VHC9541FK TC74VHCT9541AFK		
	Transceiver	Octal		20	TC74VHC245FK	TC74VHCT245AFK	TC74VHCV245FK		
				14	TC74VHC74FK				
		Hex		16	TC74VHC174FK				
			Octal		20	TC74VHC273FK			TC74VHC9273FK TC74VHCT9273FK
	3-state	Octal		20	TC74VHC374FK		TC74VHCV374FK		
				20	TC74VHC574FK	TC74VHCT574AFK	TC74VHCV574FK		
	Latch	3-state	Octal		20	TC74VHC373FK	TC74VHCT373FK		
					20	TC74VHC573FK	TC74VHCT573AFK	TC74VHCV573FK	
	Multi-vibrator		Dual		16	TC74VHC123AFK			
					16	TC74VHC221AFK			
Decoder	3 to 8 line	Single		16	TC74VHC138FK	TC74VHCT138AFK			
				16	TC74VHC238FK				
2 to 4 line	Dual		16	TC74VHC139FK					
			14	TC74VHC164FK					
Shift Register	8bit	S-in / P-out		16	TC74VHC165FK		TC74VHC9164FK		
		S-in / P-out, P-in / S-out		16					
		P-in / S-out		16					
		3-state		16	TC74VHC595FK		TC74VHC9595FK		
Counter	Binary	Single 4bit with	Async. Clear	16	TC74VHC161FK				
			Sync. Clear	16	TC74VHC163FK				
		Dual	4bit	14	TC74VHC393FK				
			14-stage	16	TC74VHC4020FK				
		Single	12-stage	16	TC74VHC4040FK				
Multi-plexer	Digital	Dual-4ch.		16	TC74VHC153FK				
		Quad-2ch.		16	TC74VHC157FK				
	Analog	Single-8ch.		16	TC74VHC4051AFK				
		Dual-4ch.		16	TC74VHC4052AFK				
		Triple-2ch.		16	TC74VHC4053AFK				
Other	Analog switch Quad		14	TC74VHC4066AFK					

Standard Logic 74LCX Series, 74VCX Series (US14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

US14			US16			US20			Features		
									• Small mounting area and thin package		
4.0 x 4.0			4.0 x 4.0			5.0 x 4.0					
Series name							LCX		VCX		
Characteristics and Features		Supply voltage range					1.65 to 3.6 V to 5.5 V (05 and 07)		1.2 to 3.6 V		
		Output current @V _{cc} = 3 V					±24 mA		±24 mA		
		Power down protection on inputs					Yes		Yes		
		Power down protection on outputs					Yes		Yes		
Function						Pin	-		-		
Gate / Buffer	NAND	Quad				14	TC74LCX00FK		TC74VCX00FK		
	AND	Quad				14	TC74LCX08FK		TC74VCX08FK		
	NOR	Quad				14	TC74LCX02FK		TC74VCX02FK		
	OR	Quad				14	TC74LCX32FK		TC74VCX32FK		
	Exclusive-OR	Quad				14	TC74LCX86FK				
	Inverter	Hex	Open-drain			14	TC74LCX04FK		TC74VCX04FK		
						14	TC74LCX05FK				
						14	TC74LCX14FK		TC74VCX14FK		
	Buffer	Hex	Open-drain			14	TC74LCX07FK				
						14	TC74LCX125FK		TC74VCX125FK		
	3-state Buffer	Quad				14	TC74LCX126FK				
						14			TC74VCX2125FK		
						14					
		Octal	Inverted				20	TC74LCX240FK			
							20	TC74LCX540FK			
							20	TC74LCX244FK		TC74VCX244FK	
							20	TC74LCX541FK		TC74VCX541FK	
			Series resistor				20			TC74VCX2244FK	
							20			TC74VCX2541FK	
							20			TC74VCX245FK	
							20	TC74LCX245FK			
Flip-Flop		Dual			14	TC74LCX74FK					
					20	TC74LCX273FK					
	3-state	Octal			20	TC74LCX374FK					
20					TC74LCX574FK		TC74VCX574FK				
Latch	3-state	Octal			20	TC74LCX373FK					
					20	TC74LCX573FK					
Decoder	3 to 8 line	Single				16	TC74LCX138FK		TC74VCX138FK		
Multi-plexer	Digital	Quad-2ch.			16	TC74LCX157FK		TC74VCX157FK			
					16	TC74LCX257FK		TC74VCX257FK			

① MOSFETs

② Tr./BRTs

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

⑨ Packages

■ Standard Logic 74HC Series, TC4000B Series (SOIC14 / 16 / 20, SOP14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

SOIC14	SOIC16	SOIC20	SOP14	SOP16	SOP20
					
8.65 x 6.0	9.9 x 6.0	12.8 x 10.3	10.3 x 7.8	10.3 x 7.8	12.8 x 7.8

Series name				SOIC Package		SOP Package		Standard series		
				HC	HCT (TTL Input)	HC	HCT (TTL Input)			
Characteristics and Features	Supply voltage range			2 to 6 V	4.5 to 5.5 V	2 to 6 V	4.5 to 5.5 V	3 to 18 V		
	Output current @V _{CC} = 4.5 V			±4 or ±6 mA	±4 or ±6 mA	±4 or ±6 mA	±4 or ±6 mA	±0.51 mA (@V _{CC} = 5 V)		
	Power down protection on inputs			No		No		No		
	Power down protection on outputs			No		No		No		
Function				Pin	-	-	-	-		
Gate / Buffer	NAND	Quad		14	74HC00D ↑		TC74HC00AF	TC4011BF		
			Open-drain	14	74HC03D ↑					
		Schmitt	14			TC74HC132AF	TC4093BF			
		Dual	4-input	14			TC74HC20AF			
	AND	Quad		14	74HC08D ↑		TC74HC08AF	TC4081BF		
		Dual	4-input	14			TC74HC21AF			
	NOR	Quad		14			TC74HC02AF	TC4001BF		
	OR	Quad		14	74HC32D ↑		TC74HC32AF	TC4071BF		
	Exclusive-OR Inverter	Quad		14	74HC86D ↑			TC4030BF		
		Hex		14	74HC04D ↑		TC74HC04AF	TC74HCT04AF		
	Buffer				16			TC74HC4049AF	TC4049BF	
				Unbuffer	14			TC74HCU04AF	TC4069UBF	
				Open-drain	14	74HC05D ↑		TC74HC05AF		
				Schmitt	14	74HC14D ↑	74HCT14D ↑	TC74HC14AF	TC4584BF	
					16			TC74HC4050AF	TC4050BF	
					Open-drain	14			TC74HC07AF	
		3-state Buffer	Quad			14	74HC125D ↑		TC74HC125AF	
						14	74HC126D ↑		TC74HC126AF	
			Hex	Universal		14			TC74HC365AF	
						14			TC74HC366AF	
									TC74HCT7007AF	
									TC74HC240AF	TC74HCT240AF
	Octal		Inverted		20			TC74HC540AF	TC74HCT540AF	
					20			TC74HC7240AF		
	Transceiver	Octal	Inverted		20			TC74HC241AF		
					20			TC74HC244AF	TC74HCT244AF	
			20			TC74HC7244AF				
			20			TC74HC541AF	TC74HCT541AF			
			20			TC74HC640AF				
			20	74HC245D ↑	74HCT245D ↑	TC74HC245AF				
Flip-Flop			Dual Hex		14			TC74HC74AF	TC4013BF	
					16	74HC175D ↑		TC74HC175AF		
3-state			Octal		20	74HC273D ↑		TC74HC273AF		
					20	74HC374D ↑		TC74HC374AF		
Latch	8-Bit Addressable Latch	3-state Octal		20	74HC574D ↑		TC74HC574AF			
				16	74HC259D ↑					
				20	74HC373D ↑		TC74HC373AF			
Multi-vibrator	Dual Monostable			20	74HC573D ↑		TC74HC573AF			
				16			TC74HC123AF			
				16			TC74HC423AF			
Decoder	3 to 8 line	Single		16			TC74HC42AF			
				16	74HC138D ↑		TC74HC138AF			
				16	74HC238D ↑					
	3 to 8 line / Latch			16	74HC237D ↑					
				16				TC4511BF		
			Shift Register	8bit			14	74HC164D ↑		
	16						TC74HC165AF	TC4021BF		
	16	74HC166D ↑								
				16	74HC594D ↑					
				16	74HC595D ↑		TC74HC595AF			
				16				TC4094BF		
Counter	Binary			14-stage		TC74HC4020AF	TC4020BF			
				12-stage		TC74HC4040AF	TC4040BF			
				Single 14-Stage / Oscillator		TC74HC4060AF				
				Single Decade Counter/Divider			TC4017BF			
				Dual Binary Up Counter			TC4520BF			
				Programmable Divider / Timer						
Multi-plexer	Digital			16		TC74HC7292AF				
				16	74HC151D ↑		TC74HC151AF			
				16	74HC251AF					
				16	74HC153AF					
				16	74HC253AF					
				16	74HC157AF					
	Analog			16	74HC4051D ↑	74HCT4051D ↑	TC74HC4051AF	TC4051BF		
				16	74HC4052D ↑	74HCT4052D ↑	TC74HC4052AF	TC4052BF		
				16	74HC4053D ↑	74HCT4053D ↑	TC74HC4053AF	TC4053BF		
Other	Analog switch	Quad		14	74HC4066D ↑		TC74HC4066AF	TC4066BF		
				14						

† Operating temperature: T_{opr} = -40 to 125 °C

Standard Logic TC74VCX Series, TC74LCX Series (TSSOP14 / 16 / 20 / 48 Package Products)

Package Dimensions (unit: mm)

TSSOP14	TSSOP16	TSSOP20	TSSOP48
			
5.0 x 6.4	5.0 x 6.4	6.5 x 6.4	12.5 x 8.1

Series name				TSSOP Package	
				TC74VCX	TC74LCX
Characteristics and Features				Supply voltage range	1.2 to 3.6 V
				Output current @V _{CC} = 3 V	1.65 to 3.6 V
				±24 mA	±24 mA
				Power down protection on inputs	Yes
				Power down protection on outputs	Yes
Function				Pin	
Gate / Buffer	NAND	Quad	14	TC74VCX00FT †	
	AND	Quad	14	TC74VCX08FT †	
	NOR	Quad	14	TC74VCX02FT †	
	OR	Quad	14	TC74VCX32FT †	
	Inverter	Hex	14	TC74VCX04FT †	
		Schmitt	14	TC74VCX14FT †	
	3-state Buffer	Quad	14	TC74VCX125FT †	
		Series resistor	14	TC74VCX2125FT †	
			20	TC74VCX244FT †	
		Series resistor	20	TC74VCX541FT †	
			20	TC74VCX2244FT †	
			20	TC74VCX2541FT †	
		16bit	48		TC74LCX16244 †
	Transceiver	Octal	20	TC74VCX245FT †	
		16bit	48	TC74VCX16245 †	TC74LCX16245 †
		Bus hold	48	TC74VCXH16245 †	
			48	TC74VCXR162245 †	
			48	T74VCXHR162245 †	
		Bus hold + Series resistor	48		
Flip-Flop	3-state	Octal	14	TC74VCX574FT †	
Decoder	3 to 8 line	Single	16	TC74VCX138FT †	
Multi-plexer	Digital	Quad-2ch.	16	TC74VCX157FT †	
		3-state	16	TC74VCX257FT †	

† Operating temperature: T_{opr} = -40 to 125 °C

① MOSFETs

② Tr./BRTs

③ Diodes

④ Power Management ICs

⑤ Linear ICs

⑥ Sensors

⑦ General Purpose Logic ICs

⑧ RF Devices

⑨ Packages

7-3 Bus Switches

■ High-Speed Transmission Type

Package Dimensions (unit: mm)

High-Speed Transmission Type

XQFN16	TQFN20
Bottom View	Bottom View
	
2.4 x 1.6	4.5 x 2.5

Recommended application	Interface Speed	Part Number	Package	Number of lane	Specification			Pin Assignment	Switch function
					Supply Voltage Range	Band width @ -3 dB (typ.)	Quiescent Supply Current (max)		
USB4® PCIe®-Gen5 Thunderbolt 4™ DP2.0™	to 32 Gbps	TDS4A212MX ☆	XQFN16	1 lane	1.6 to 3.6 V	26.2 GHz @V _{cc} = 1.6 to 3.6 V	150 μA @V _{cc} = 3.6 V		SPDT
		TDS4B212MX ☆				27.5 GHz @V _{cc} = 1.6 to 3.6 V			
USB3.1 PCIe®-Gen3	to 10 Gbps	TC7PCI3212MT	TQFN20	1 lane	3 to 3.6 V	11.5 GHz @V _{cc} = 3.3 V	500 μA @V _{cc} = 3.6 V		SPDT
		TC7PCI3215MT							

for USB2.0 and others

UQFN10B	TSSOP14
Bottom View	
	
1.4 x 1.8	5.0 x 6.4

Recommended application	Interface Speed	Part Number	Package	Number of circuit	Specification			Pin Assignment	Switch function
					Supply Voltage Range	Band width @-3 dB (typ.)	Quiescent Supply Current (max)		
USB2.0 PCIe®-Gen1 HDMI™1.4 SATA2.0 SAS1.0	to 3.4 Gbps	TC7USB40MU	UQFN10B	2	2.3 to 4.3 V	1.5 GHz @V _{cc} = 3.3 V	1 μA @V _{cc} = 4.3 V		SPDT
		TC7USB42MU							
		TC7USB40FT	TSSOP14						
		TC7USB42FT							

☆ New Products

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General Purpose Bus Switches

Package Dimensions (unit: mm)

USV (SOT-353)	XSON6 (MP6D)	US6 (SOT-363)	US8 (SOT-765)	US14	US16	US20	TSSOP14B	TSSOP16B	TSSOP20B
	Bottom View 								
2.0 x 2.1	1.45 x 1.0	2.0 x 2.1	2.0 x 3.1	4.0 x 4.0	4.0 x 4.0	5.0 x 4.0	5.0 x 6.4	5.0 x 6.4	6.5 x 6.4

5 V Bus Switch

Switch function	Part Number	Package	Number of circuit	Switch type	Specification			
					Supply Voltage Range	Switch I/O Capacitance @Switch OFF (typ.)	Switch ON Resistance @V _{cc} = 4.5 V, V _{is} = 0 V (typ.)	Quiescent Supply Current (max)
SPST	TC7SB66CFU # †	USV	1	P-ch + N-ch	1.65 to 5.5 V	5 pF @V _{cc} = 5 V	4 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 5.5 V
	TC7SB67CFU # †							
	TC7WB66CFK # †	US8	2					
	TC7WB67CFK # †							
SPDT	TC7SB3157CFU # †	US6	1	P-ch + N-ch	1.65 to 5.5 V	5 pF @V _{cc} = 5 V	4 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 5.5 V
	TC7SB3157DL6X	XSON6 (MP6D)						

Low-Voltage Bus Switch

Switch function	Part Number	Package	Number of circuit	Switch type	Specification			
					Supply Voltage Range	Switch I/O Capacitance	Switch ON Resistance @V _{cc} = 3 V, V _{is} = 0 V (typ.)	Quiescent Supply Current
SPST	TC7SBL66CFU # †	USV	1	P-ch + N-ch	1.65 to 3.6 V	3.5 pF @V _{cc} = 3 V	5.5 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 3.6 V
	TC7SBL384CFU # †							
	TC7WBL3305CFK # †	US8	2				6 Ω @I _{is} = 30 mA	
	TC7WBL3306CFK # †							
	TC7MBL3125CFK	US14	4				6.5 Ω @I _{is} = 30 mA	
	TC7MBL3125CFT # †	TSSOP14B						
	TC7MBL3126CFK	US14						
	TC7MBL3126CFT # †	TSSOP14B						
TC7MBL3245CFK	US20	8						
TC7MBL3245CFT # †	TSSOP20B							
SPDT	TC7MBL3257CFK	US16	4	P-ch + N-ch	1.65 to 3.6 V	5 pF @V _{cc} = 3V, A-port	8.5 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 3.6 V
	TC7MBL3257CFT # †	TSSOP16B						
SP4T	TC7MBL3253CFK	US16	2	P-ch + N-ch	1.65 to 3.6 V	9 pF @V _{cc} = 3V, A-port	9 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 3.6 V
	TC7MBL3253CFT # †	TSSOP16B						

This device is compliant with the reliability requirements of AEC-Q100

† Operation temperature is -40 to 125 °C

7-4 Level Shifters

Package Dimensions (unit: mm)

fsv (SOT-953)	UF6 (SOT-363F)	USV (SOT-353)	US8 (SOT-765)	US16	TSSOP16B	TSSOP48
						
1.0 x 1.0	2.0 x 2.1	2.0 x 2.1	2.0 x 3.1	4.0 x 4.0	5.0 x 6.4	12.5 x 8.1

Bus Buffer Type

Direction	Part Number	Package	Bit Count	Control Input	Function								
					Supply Voltage Range		Gate or Buffer	Sleep Mode	Low Noise	Series Resistor or Bus Hold			
					V _{CCA} (V)	V _{CCB} (V)							
Bidirectional	TC7MP3125FK	US16	4	Active-Low (A side)	1.1 to 2.7	1.65 to 3.6	3-State Buffer	✓					
	TC7MP3125FT # †	TSSOP16B						✓					
	TC7MPN3125FK	US16						✓	✓				
	TC7MPN3125FT # †	TSSOP16B						✓	✓				
	74LVC2T45FK ☆ †	US8	2	None	1.65 to 5.5		Buffer						
	74AVC4T245FT ☆ †	TSSOP16B	4	Active-Low (A side)	0.8 to 3.6		3-State Buffer			Bus Hold			
	74AVCH4T245FT ☆ †												
	74AVC4T345FT ☆ †												
	TC74VCX163245 †												
	TC74VCX164245 †	TSSOP48	16	Active-Low (B side)	2.3 to 3.6	1.65 to 2.7							
	TC74VCX164245 †				1.65 to 2.7	2.3 to 3.6							
	TC74LCXR163245 †				4.5 to 5.5	2.3 to 3.6			Series Resistor				
	TC74LCX164245 †												
	TC74LCXR164245 †						Series Resistor						
	Unidirectional	TC7SP3125TU	UF6	1	Active-Low (A side)	1.1 to 2.7	1.65 to 3.6	3-State Buffer	✓				
		TC7SPN3125TU							✓	✓			
TC7WP3125FK †		US8	2	Active-Low (A side)	1.65 to 5.5				(Single Supply)	3-State Buffer	✓	✓	
TC7WPN3125FK †											✓	✓	
74LV4T125FT # †		TSSOP16B	4	Active-Low									
74LV4T125FK †		US16											
74LV4T126FT # †		TSSOP16B		Active-High									
74LV4T126FK †		US16											
7UL1T00FS †		fsv	1	None	2.3 to 3.6	(Single Supply)	NAND						
7UL1T02FS †							NOR						
7UL1T04FS †							Inverter						
7UL1T08FS †							AND						
7UL1T32FS †							OR						
7UL1T34FS †							Buffer						
7UL1T86FS †				Exclusive-OR									
7UL1T125FS †				3-State Buffer									
7UL1T126FS †	NAND												
7UL1T00FU †	USV	1	None	NOR									
7UL1T02FU †				Inverter									
7UL1T04FU †				AND									
7UL1T08FU †				OR									
7UL1T32FU †				Buffer									
7UL1T34FU †				Exclusive-OR									
7UL1T86FU †			3-State Buffer										
7UL1T125FU †													
7UL1T126FU †			Active-High										

☆ New Products

This device is compliant with the reliability requirements of AEC-Q100

† Operation temperature is -40 to 125 °C

UF6 (SOT-363F)	US8 (SOT-765)	US14	US20	TSSOP14B	TSSOP20B	XSON6 (MP6D)
						
2.0 x 2.1	2.0 x 3.1	4.0 x 4.0	5.0 x 4.0	5.0 x 6.4	6.5 x 6.4	Bottom View 1.45 x 1.0

Bus Buffer Type

Direction	Part Number	Package	Bit Count	Control Input	Function				
					Supply Voltage Range		Gate or Buffer	Sleep Mode	Low Noise
					V _{CCA} (V)	V _{CCB} (V)			
Unidirectional	7UL1T00NX ★ †	XSON6 (MP6D)	1	None	2.3 to 3.6	- (Single Supply)	NAND		
	7UL1T02NX ★ †						NOR		
	7UL1T04NX ★ †						Inverter		
	7UL1T08NX ★ †						AND		
	7UL1T32NX ★ †						OR		
	7UL1T34NX ★ †						Buffer		
	7UL1T86NX ★ †						Exclusive-OR		
	7UL1T125NX ★ †			Active-Low			3-State Buffer		
	7UL1T126NX ★ †			Active-High					
	7UL2T00FK †	US8	2	None	2.3 to 3.6	- (Single Supply)	NAND		
	7UL2T02FK †		3				NOR		
	7UL3T04FK †		2				Inverter		
	7UL2T08FK †		3				AND		
	7UL2T32FK †		2				OR		
	7UL3T34FK †		3				Buffer		
	7UL2T86FK †		2				Exclusive-OR		
	7UL2T125FK †		2	Active-Low			3-State Buffer		
	7UL2T126FK †		2	Active-High					

Bus Switch Type

Switch function	Part Number	Package	Bit Count	Control Input	Specification			
					Supply Voltage Range		Switch I/O Capacitance @Switch OFF (typ.)	Switch ON Resistance @V _{CCA} = 3 V, V _{CCB} = 4.5 V, V _{IS} = 0 V (max)
					V _{CCA} (V)	V _{CCB} (V)		
SPST	TC7SPB9306TU	UF6	1	Active-High (A side)	1.65 to 5	2.3 to 5.5	7 pF @V _{CCA/B} = 3.3 V	8 Ω @I _{IS} = 30 mA
	TC7SPB9307TU			Active-Low (A side)				
	TC7WPB9306FK # †	US8	2	Active-High (A side)				
	TC7WPB9307FK # †			Active-Low (A side)				
	TC7QPB9306FK	US14	4	Active-High (A side)				
	TC7QPB9306FT # †	TSSOP14B		Active-Low (A side)				
	TC7QPB9307FK	US14		Active-High (A side)				
	TC7QPB9307FT # †	TSSOP14B		Active-Low (A side)				
	TC7MPB9307FK	US20	8	Active-Low (A side)				
	TC7MPB9307FT # †	TSSOP20B		Active-Low (A side)				
SPDT	TC7MPB9326FK	US14	2	Active-High (A side)	1.65 to 5	2.3 to 5.5	7 pF @V _{CCA/B} = 3.3 V	8 Ω @I _{IS} = 30 mA
	TC7MPB9326FT # †	TSSOP14B		Active-Low (A side)				
	TC7MPB9327FK	US14		Active-High (A side)				
	TC7MPB9327FT # †	TSSOP14B		Active-Low (A side)				

☆ New Products, ★ Under Development (The specification is subject to change without notice.)

This device is compliant with the reliability requirements of AEC-Q100

† Operation temperature is -40 to 125 °C

7-5 Part Naming Conventions

Standard Logic

74VHC T 244 A FT

Package suffix

FT: TSSOP, FK: US (VSSOP), F: SOP, D: SOIC, No letter: TSSOP48

Revision code or standardized product

Standardized product function number

Circuit configuration or performance class

Ex.) T: TTL-level input, U: Unbuffered

TOSHIBA CMOS family (group) name

TC: Standard CMOS logic
TC74HC, 74HC: High-speed CMOS logic
TC74VHC, 74VHC: Very-high-speed CMOS logic
TC74LCX, 74LCX: Low-voltage CMOS logic
TC74VCX, T74VCX: Low-voltage CMOS logic

One-Gate Logic

TC7SZ 00 FS

Package suffix

FS: fSV, FE: ES6 / ES6, FU: USV / US6 / SM8, FK: US8, F: SMV

Revision code or standardized product

Standardized product function number

TOSHIBA L-MOS (One-gate Logic) family (group) name

TC7SH, TC7WH: VHS Series
TC7SET: VHS series (TTL input level)
TC7SZ, TC7WZ: SHS series

7UL 1 G 00 FS

Package suffix

FS: fSV, FU: USV, FK: US8, NX: XSON6 (MP6D)

Revision code or standardized product

Standardized product function number

Product Sub family (group) name

G: LVP series
T: LVP series (with signal level translation)

Number of gate

1: Single, 2: Dual, 3: Triple

TOSHIBA L-MOS (One-gate Logic) family (group) name

7UL: Ultra Low voltage Series

8. Radio-Frequency Devices

RF Diodes

Package Dimensions (unit: mm)

SOD-923	ESC (SOD-523)	USC (SOD-323)
		
1.0 x 0.6	1.6 x 0.8	2.5 x 1.25

Variable Capacitance Diodes

Application	Part Number	Structure	Package	Absolute Maximum Ratings	Electrical Characteristics (Ta= 25 °C)						
					V _R (V)	C _T upper (pF)	@V _R (V)	C _T lower (pF)	@V _R (V)	C _T upper / C _T lower	r _s typ. (Ω)
VCO	1SV285	Single	ESC	10	4.5	1	2	4	2.3	0.42	1
	1SV277	Single	USC	10	4.5	1	2	4	2.3	0.42	1
	1SV311	Single	ESC	10	9.7 to 11.1	1	4.45 to 5.45	4	2.1	0.28	1
	1SV310	Single	USC	10	9.7 to 11.1	1	4.45 to 5.45	4	2.1	0.28	1
	1SV281	Single	ESC	10	16	1	8	4	2	0.28	1
	1SV270	Single	USC	10	16	1	8	4	2	0.28	1
	1SV305	Single	ESC	10	18.3	1	6.1	4	3	0.27	1
	1SV304	Single	USC	10	18.3	1	6.1	4	3	0.27	1
	1SV323	Single	ESC	10	26.5 to 29.5	1	6 to 7.1	4	4.3	0.4	4
	1SV322	Single	USC	10	26.5 to 29.5	1	6 to 7.1	4	4.3	0.4	4
	1SV325	Single	ESC	10	44 to 49.5	1	9.2 to 12	4	4.3	0.4	4
	1SV324	Single	USC	10	44 to 49.5	1	9.2 to 12	4	4.3	0.4	4
	JDV2S36E	Single	ESC	10	44 to 49.5	1	5.4 to 7.3	6	7.5	0.4	4
	1SV280	Single	ESC	15	3.8 to 4.7	2	1.5 to 2	10	2.4	0.44	1
	JDV2S42FS ☆	Single	SOD-923	15	3.8 to 4.7	2	1.5 to 2	10	2.4	0.44	1
	1SV239	Single	USC	15	4.25	2	1.75	10	2.4	0.44	1
	1SV279	Single	ESC	15	14 to 16	2	5.5 to 6.5	10	2.5	0.2	5
	1SV229	Single	USC	15	14 to 16	2	5.5 to 6.5	10	2.5	0.2	5
	JDV2S41AFS ☆	Single	SOD-923	15	14 to 16	2	5.5 to 6.5	10	2.5	0.2	5

☆ New Products

RF Diodes

Package Dimensions (unit: mm)

SL2 (SOD-962)	SOD-923	ESC (SOD-523)	USC (SOD-323)	VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	S-Mini (SOT-346)
Bottom View							
0.62 x 0.32	1.0 x 0.6	1.6 x 0.8	2.5 x 1.25	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.5

Schottky Barrier Diodes

Feature	Part Number	Structure	Package	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					
				V _R (V)	I _F (mA)	V _F typ. (V)	@I _F (mA)	I _R max (μA)	@V _R (V)	C _T typ. (pF)	@V _R (V)
Low V _F	JDH2S02SL	Single	SL2	10	10	0.24	1	25	0.5	0.25	0.2
	JDH2S02FS ☆	Single	SOD-923	10	10	0.24	1	25	0.5	0.25	0.2
Standard	1SS315	Single	USC	5	30	0.25	2	25	0.5	0.6	0.2
	1SS154	Single	S-Mini	6	30	0.5	10	0.5	5	0.8	0
	JDH3D01FV	Series	VESM	4	25	0.25	2	25	0.5	0.6	0.2
	JDH3D01S	Series	SSM	4	25	0.25	2	25	0.5	0.6	0.2
	1SS295	Series	S-Mini	4	30	0.25	2	25	0.5	0.6	0.2
	1SS271	Series	S-Mini	6	30	0.5	10	0.5	5	0.8	0

☆ New Products

Switching Diodes

Feature	Part Number	Structure	Package	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					
				V _R (V)	I _F (mA)	V _F typ. (V)	@I _F (mA)	C _T typ. (pF)	@V _R (V)	r _s typ. (Ω)	@I _F (mA)
Standard PIN diode	1SV308	Single	ESC	30	50	0.95	50	0.3	1	1	10
	1SV307	Single	USC	30	50	0.95	50	0.3	1	1	10
	JDP3C02AU	Cathode com.	USM	30	50	0.89	50	0.28	1	1	10
RF switching diode	1SS381	Single	ESC	30	100	0.85 (max)	2	0.7	6	0.6	2
	1SS314	Single	USC	30	100	0.85 (max)	2	0.7	6	0.5	2
	1SS364	Cathode com.	SSM	30	50	0.85 (max)	2	0.85	6	0.6	2
	1SS312	Cathode com.	USM	30	50	0.85 (max)	2	0.8	6	0.6	2
	1SS313	Anode com.	USM	30	50	0.85 (max)	2	0.8	6	0.6	2
	1SS268	Cathode com.	S-Mini	30	50	0.85 (max)	2	0.8	6	0.6	2
	1SS269	Anode com.	S-Mini	30	50	0.85 (max)	2	0.8	6	0.6	2

Part Naming Conventions

Radio-Frequency Diode (EIAJ registration products)

Ex.) 1 S S 381
① ② ③ ④

- ① The value that subtracted 1 from the total number of terminals
- ② S stands for Semiconductor
- ③ The kind of diode
This section shows the kind of the Radio Frequency diode being used.
(It is omitted in certain cases.)
S: detection use, Frequency conversion use, and switching use
V: variable capacitance diode, PIN diode
- ④ Serial number

Radio-Frequency Diode (EIAJ un-registration products)

Ex.) JD V 2 S 36 E
① ② ③ ④ ⑤ ⑥

- ① JD means High-frequency diode
- ② The kind of devices
This section shows the kind of the devices being used.
It is classified into H, P, S, and V by the devices being loaded.
H: schottky barrier diode
P: PIN diode
S: band switching diode
V: variable capacitance diode
- ③ The number of terminals
- ④ Internal connection
This section shows the kind of the internal connection of a product.
S: single
C: cathode common
P: parallel
- ⑤ Serial number
- ⑥ Package type

AU	USM
S	SSM
E	ESC
SL	SL2
FV	VESM
FS, AFS	SOD-923

9. Device Packages

2 Pin packages

SL2 (SOD-962) (0.62 x 0.32) Package dimension unit: mm Land pattern example unit: mm	CL2E (1.0 x 0.6) Package dimension unit: mm Land pattern example unit: mm	SOD-923 (1.0 x 0.6) Package dimension unit: mm Land pattern example unit: mm
CST2 (SOD-882) (1.0 x 0.6) Package dimension unit: mm Land pattern example unit: mm	CST2B (1.2 x 0.8) Package dimension unit: mm Land pattern example unit: mm	CST2C (SOD-963) (1.6 x 0.8) Package dimension unit: mm Land pattern example unit: mm
ESC (SOD-523) (1.6 x 0.8) Package dimension unit: mm Land pattern example unit: mm	USC (SOD-323) (2.5 x 1.25) Package dimension unit: mm Land pattern example unit: mm	US2H (SOD-323HE) (2.5 x 1.4) Package dimension unit: mm Land pattern example unit: mm

3 Pin packages

CST3C (0.8 x 0.6)		CST3 (SOT-883) (1.0 x 0.6)		VESM (SOT-723) (1.2 x 1.2)	
Package dimension unit: mm 		Package dimension unit: mm 		Package dimension unit: mm 	
Land pattern example unit: mm 		Land pattern example unit: mm 		Land pattern example unit: mm 	
SSM (SOT-416) (1.6 x 1.6)		USM (SOT-323) (2.0 x 2.1)		UFM (SOT-323F) (2.0 x 2.1)	
Package dimension unit: mm 		Package dimension unit: mm 		Package dimension unit: mm 	
Land pattern example unit: mm 		Land pattern example unit: mm 		Land pattern example unit: mm 	
S-Mini (SOT-346) (2.9 x 2.5)		SOT23 (SOT-23) (2.9 x 2.4)		SOT-23F (2.9 x 2.4)	
Package dimension unit: mm 		Package dimension unit: mm 		Package dimension unit: mm 	
Land pattern example unit: mm 		Land pattern example unit: mm 		Land pattern example unit: mm 	

4 Pin packages

WCSP4E (0.645 x 0.645) Package dimension unit: mm Land pattern example unit: mm	WCSP4F (0.645 x 0.645) Package dimension unit: mm Land pattern example unit: mm	WCSP4G (0.645 x 0.645) Package dimension unit: mm Land pattern example unit: mm
WCSP4D (0.79 x 0.79) Package dimension unit: mm Land pattern example unit: mm	SDFN4E (0.8 x 0.8) Package dimension unit: mm Land pattern example unit: mm	WCSP4C (0.9 x 0.9) Package dimension unit: mm Land pattern example unit: mm
DFN4D (1.0 x 1.0) Package dimension unit: mm Land pattern example unit: mm	DFN4E (1.0 x 1.0) Package dimension unit: mm Land pattern example unit: mm	DFN4F (1.0 x 1.0) Package dimension unit: mm Land pattern example unit: mm

4 Pin packages

5 Pin packages

DFN4A (1.2 x 1.2)	DFN5 (1.3 x 0.8)	DFN5B (1.2 x 1.2)
Package dimension unit: mm 	Package dimension unit: mm 	Package dimension unit: mm
Land pattern example unit: mm 	Land pattern example unit: mm 	Land pattern example unit: mm
fSV (SOT-953) (1.0 x 1.0)	ESV (SOT-553) (1.6 x 1.6)	UFV (SOT-353F) (2.0 x 2.1)
Package dimension unit: mm 	Package dimension unit: mm 	Package dimension unit: mm
Land pattern example unit: mm 	Land pattern example unit: mm 	Land pattern example unit: mm

6 Pin packages

USV (SOT-353) (2.0 x 2.1)	SMV (SOT-25) (2.9 x 2.8)	WCSP6E (1.2 x 0.8)
Package dimension unit: mm 	Package dimension unit: mm 	Package dimension unit: mm
Land pattern example unit: mm 	Land pattern example unit: mm 	Land pattern example unit: mm

WCSP6F (1.2 x 0.8) Package dimension unit: mm Land pattern example unit: mm	WCSP6G (1.2 x 0.8) Package dimension unit: mm Land pattern example unit: mm	DFN6 (1.25 x 1.0) Package dimension unit: mm Land pattern example unit: mm
MP6C (1.45 x 1.0) Package dimension unit: mm Land pattern example unit: mm	XSON6(MP6D) (1.45 x 1.0) Package dimension unit: mm Land pattern example unit: mm	WCSP6C (1.5 x 1.0) Package dimension unit: mm Land pattern example unit: mm
DFN2020(WF) (2.0 x 2.0) Package dimension unit: mm Land pattern example unit: mm	UDFN6 (SOT-1118) (2.0 x 2.0) Package dimension unit: mm Land pattern example unit: mm	UDFN6B (SOT-1220) (2.0 x 2.0) Package dimension unit: mm Land pattern example unit: mm

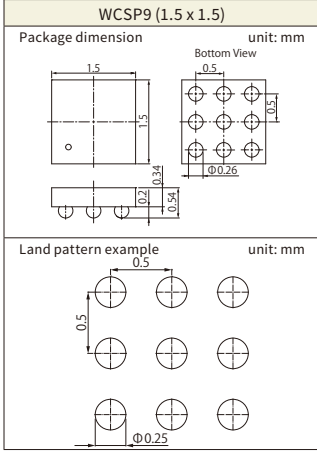
6 Pin packages

TCSP6A-172101 (2.14 x 1.67)	ES6 (SOT-563) (1.6 x 1.6)	UF6 (SOT-363F) (2.0 x 2.1)
Package dimension unit: mm 	Package dimension unit: mm 	Package dimension unit: mm
Land pattern example unit: mm 	Land pattern example unit: mm 	Land pattern example unit: mm
US6 (SOT-363) (2.0 x 2.1)	SM6 (SOT-26) (2.9 x 2.8)	TSOP6F (2.9 x 2.8)
Package dimension unit: mm 	Package dimension unit: mm 	Package dimension unit: mm
Land pattern example unit: mm 	Land pattern example unit: mm 	Land pattern example unit: mm

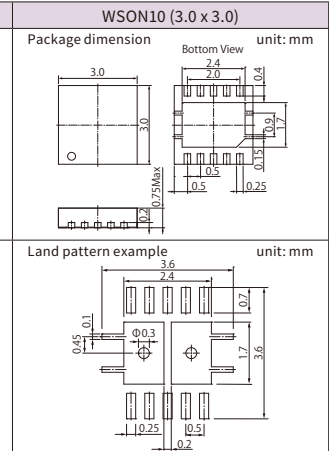
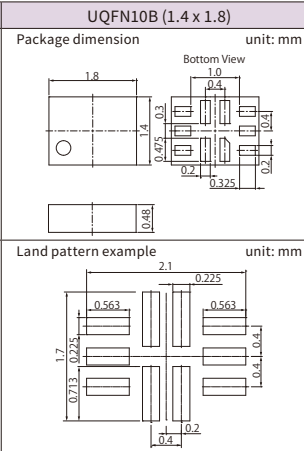
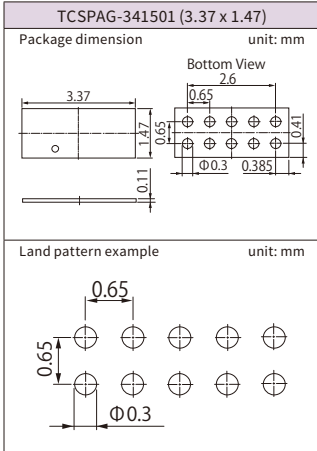
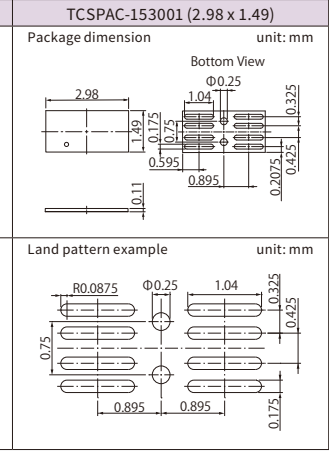
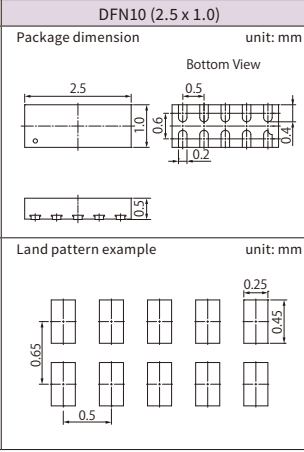
8 Pin packages

WSO8 (2.0 x 2.0)	US8 (SOT-765) (2.0 x 3.1)	SM8 (SOT-505) (2.9 x 4.0)
Package dimension unit: mm 	Package dimension unit: mm 	Package dimension unit: mm
Land pattern example unit: mm 	Land pattern example unit: mm 	Land pattern example unit: mm

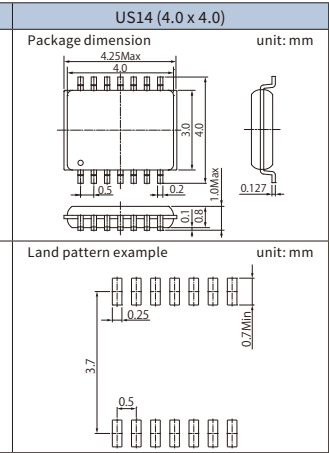
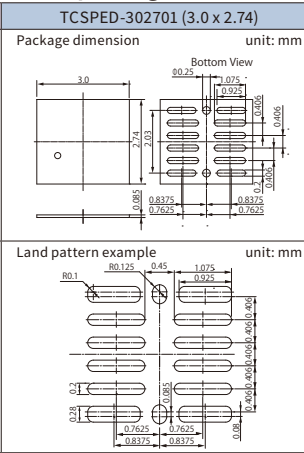
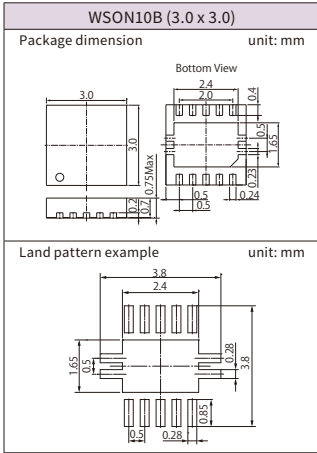
9 Pin packages



10 Pin packages



14 Pin packages



⑨ Packages

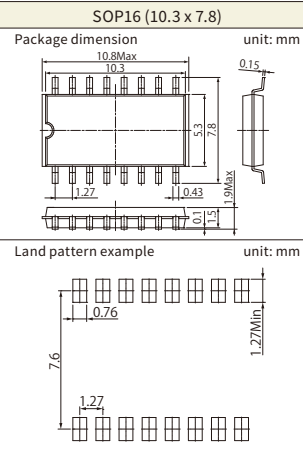
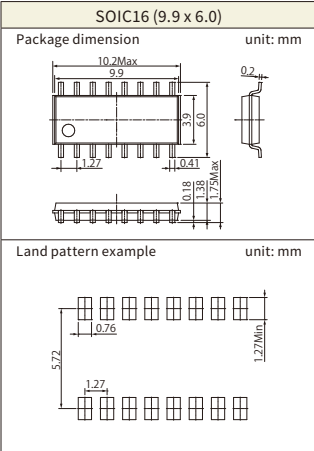
TSSOP14 (5.0 x 6.4)	TSSOP14B (5.0 x 6.4)	SOIC14 (8.65 x 6.0)
Package dimension unit: mm	Package dimension unit: mm	Package dimension unit: mm
Land pattern example unit: mm	Land pattern example unit: mm	Land pattern example unit: mm

16 Pin packages

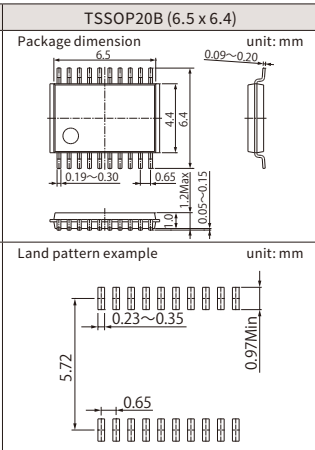
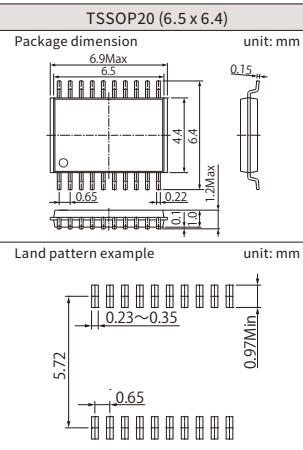
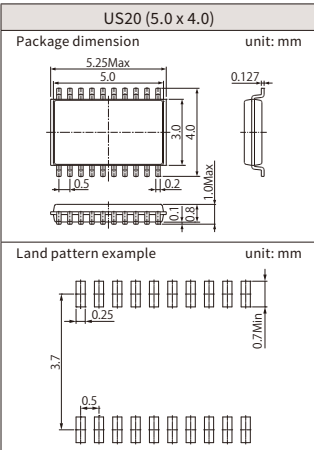
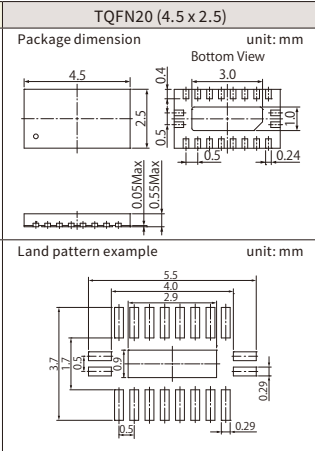
SOP14 (10.3 x 7.8)	WCSP16C (1.9 x 1.9)	XQFN16 (2.4 x 1.6)
Package dimension unit: mm	Package dimension unit: mm	Package dimension unit: mm
Land pattern example unit: mm	Land pattern example unit: mm	Land pattern example unit: mm

US16 (4.0 x 4.0)		TSSOP16 (5.0 x 6.4)		TSSOP16B (5.0 x 6.4)	
Package dimension unit: mm		Package dimension unit: mm		Package dimension unit: mm	
Land pattern example unit: mm		Land pattern example unit: mm		Land pattern example unit: mm	

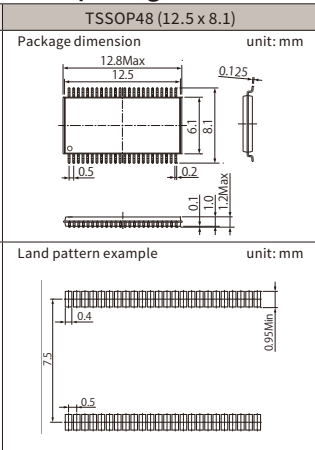
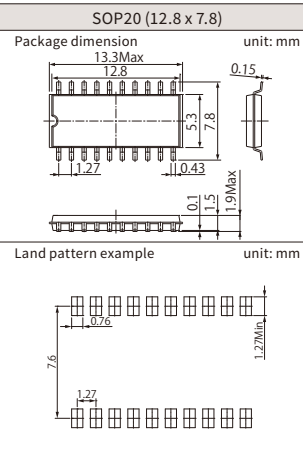
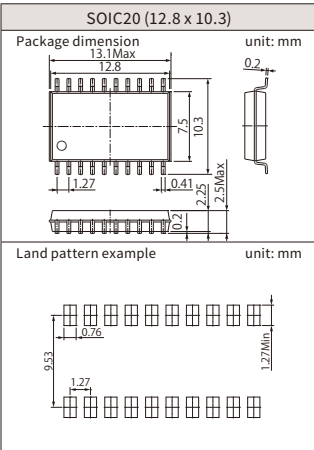
16 Pin packages



20 Pin packages



48 Pin packages



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